TPS748 1.5A, Low-Dropout Linear Regulator With Programmable Soft-Start

1 Features

- V_{OUT} range: 0.8V to 3.6V
- Ultra-low V_{IN} range: 0.8V to 5.5V
- V_{BIAS} range 2.7V to 5.5V
- Low dropout: 60 mV typical at 1.5A, V_{BIAS} = 5V
- Power-good (PG) output allows supply monitoring or provides a sequencing signal for other supplies
- 1% accuracy over line, load, and temperature (new chip)
- 2% accuracy over line, load, and temperature (legacy chip)
- Programmable soft-start provides linear voltage start-up
- V_{BIAS} permits low V_{IN} operation with good transient response
- Stable with any output capacitor ≥ 2.2µF
- Available in small, 3mm × 3mm × 1mm VSON-10 and 5mm × 5mm VQFN-20 packages

2 Applications

- Network attached storage - enterprise
- Rack servers
- Network interface cards (NIC)
- Merchant network and server PSU

3 Description

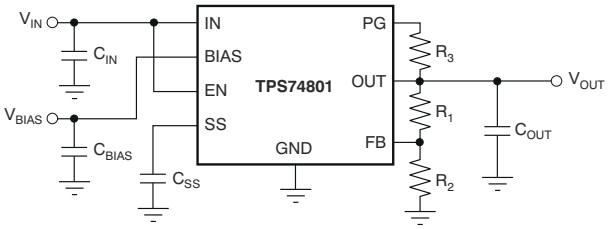
The TPS748 low-dropout (LDO) linear regulator provides an easy-to-use robust power management solution for a wide variety of applications. User-programmable soft-start minimizes stress on the input power source by reducing capacitive inrush current on start-up. The soft-start is monotonic and designed for powering many different types of processors and ASICs. The enable input and power-good output allow easy sequencing with external regulators. This complete flexibility allows a solution to be configured that meets the sequencing requirements of FPGAs, DSPs, and other applications with special start-up requirements.

A precision reference and error amplifier deliver 1% accuracy (new chip) over load, line, temperature, and process. The device is stable with any type of capacitor greater than or equal to 2.2µF, and is fully specified for T_J = –40°C to +125°C. The TPS748 is offered in a small, 3mm × 3mm, VSON-10 package, yielding a highly compact, total solution size. The device is also available in a 5mm × 5mm VQFN-20 package for compatibility with the TPS742.

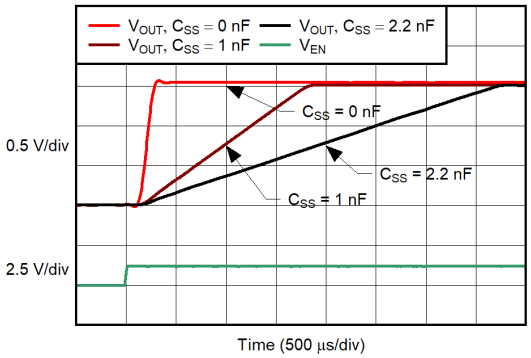
Package Information

PART NUMBER	PACKAGE(1)	PACKAGE SIZE(2)
TPS748	DRC (VSON, 10)	3mm × 3mm
	RGW (VQFN, 20)	5mm × 5mm

(1) For more information, see the *Mechanical, Packaging, and Orderable Information*.
(2) The package size (length × width) is a nominal value and includes pins, where applicable.



Typical Application Circuit (Adjustable)



Turn-On Response

An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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4 Pin Configuration and Functions

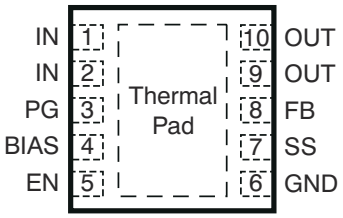


Figure 4-1. DRC Package, 10-Pin VSON With Thermal Pad (Top View)

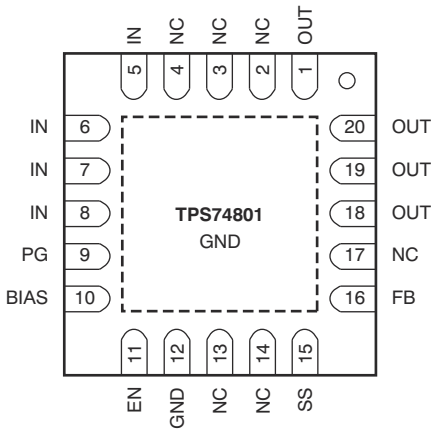


Figure 4-2. RGW Package, 20-Pin VQFN (Top View)

Table 4-1. Pin Functions

PIN			I/O	DESCRIPTION
NAME	VSON	VQFN		
BIAS	4	10	I	Bias input voltage for error amplifier, reference, and internal control circuits. A 1-µF or larger input capacitor is recommended for optimal performance. If IN is connected to BIAS, a 4.7-µF or larger capacitor must be used.
EN	5	11	I	Enable pin. Driving this pin high enables the regulator. Driving this pin low puts the regulator into shutdown mode. This pin must not be left unconnected.
FB	8	16	I	Feedback pin. The feedback connection to the center tap of an external resistor divider network that sets the output voltage. This pin must not be left floating.
GND	6	12	—	Ground
IN	1, 2	5-8	I	Input to the device. A 1-µF or larger input capacitor is recommended for optimal performance.
NC	N/A	2-4, 13, 14, 17	—	No connection. This pin can be left floating or connected to GND to allow better thermal contact to the top-side plane.
OUT	9, 10	1, 18-20	O	Regulated output voltage. A small capacitor (total typical capacitance ≥ 2.2 µF, ceramic) is needed from this pin to ground to assure stability.
PG	3	9	O	Power Good pin. An open-drain, active-high output that indicates the status of V_{OUT}. When V_{OUT} exceeds the PG trip threshold, the PG pin goes into a high-impedance state. When V_{OUT} is below this threshold the pin is driven to a low-impedance state. A pull-up resistor from 10 kΩ to 1 MΩ should be connected from this pin to a supply of up to 5.5 V. The supply can be higher than the input voltage. Alternatively, the PG pin can be left unconnected if output monitoring is not necessary.
SS	7	15	—	Soft-Start pin. A capacitor connected on this pin to ground sets the start-up time. If this pin is left unconnected, the regulator output soft-start ramp time is typically 200 µs.
Thermal pad			—	Must be soldered to the ground plane for increased thermal performance. Internally connected to ground.

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5 Specifications

5.1 Absolute Maximum Ratings

over operating temperature range (unless otherwise noted)(1)

		MIN	MAX	UNIT
V_{IN}, V_{BIAS}	Input voltage	–0.3	6	V
V_{EN}	Enable voltage	–0.3	6	V
V_{PG}	Power-good voltage	–0.3	6	V
I_{PG}	PG sink current	0	1.5	mA
V_{SS}	Soft-start voltage	–0.3	6	V
V_{FB}	Feedback voltage	–0.3	6	V
V_{OUT}	Output voltage	–0.3	V_{IN} + 0.3	V
I_{OUT}	Maximum output current	Internally limited		
	Output short-circuit duration	Indefinite		
P_{DISS}	Continuous total power dissipation	See Thermal Information		
T_J	Junction Temperature	–40	150	°C
T_{stg}	Storage Temperature	–55	150	

(1) Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

5.2 ESD Ratings

			VALUE	UNIT
$V_{(ESD)}$	Electrostatic discharge	Human body model (HBM), per ANSI/ESDA/JEDEC JS-001, all pins(1)	±2000	V
		Charged device model (CDM), per JEDEC specification JESD22-C101, all pins(2)	±500	

(1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
(2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

5.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{IN}	Input supply voltage	V_{OUT} + V_{DO} (V_{IN})	V_{OUT} + 0.3	5.5	V
V_{EN}	Enable supply voltage		V_{IN}	5.5	V
V_{BIAS} (1)	BIAS supply voltage	V_{OUT} + V_{DO} (V_{BIAS})(2)	V_{OUT} + 1.6(2)	5.5	V
V_{OUT}	Output voltage	0.8		3.3	V
I_{OUT}	Output current	0		1.5	A
C_{OUT}	Output capacitor	2.2			µF
C_{IN}	Input capacitor(3)	1			µF
C_{BIAS}	Bias capacitor	0.1	1		µF
T_J	Operating junction temperature	–40		125	°C

(1) BIAS supply is required when V_{IN} is below V_{OUT} + 1.62 V.
(2) V_{BIAS} has a minimum voltage of 2.7 V or V_{OUT} + V_{DO} (V_{BIAS}), whichever is higher.
(3) If V_{IN} and V_{BIAS} are connected to the same supply, the recommended minimum capacitor for the supply is 4.7 µF.

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5.4 Thermal Information

THERMAL METRIC[1]		TPS748				UNIT
		RGW (VQFN)	RGW (VQFN) (2)	DRC (VSON)	DRC (VSON) (2)	
		20 PINS	20 PINS	10 PINS	10 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	35.6	34.7	44.2	47.2	°C/W
$R_{\theta JC(top)}$	Junction-to-case (top) thermal resistance	33.3	31.0	50.3	63.7	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	15	13.5	19.6	19.5	°C/W
ψ_{JT}	Junction-to-top characterization parameter	0.4	1.4	0.7	4.2	°C/W
ψ_{JB}	Junction-to-board characterization parameter	15.2	13.5	17.8	19.4	°C/W
$R_{\theta JC(bot)}$	Junction-to-case (bottom) thermal resistance	3.8	3.6	4.3	3.3	°C/W

(1) For more information about traditional and new thermal metrics, see the Semiconductor and IC package thermla metrics application note.
(2) New Chip.

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5.5 Electrical Characteristics

at V_{EN} = 1.1 V, V_{IN} = V_{OUT} + 0.3 V, C_{BIAS} = 0.1 µF, C_{IN} = C_{OUT} = 10 µF, C_{NR} = 1 nF, I_{OUT} = 50 mA, V_{BIAS} = 5.0 V, and T_J = –40°C to 125°C (unless otherwise noted); typical values are at T_J = 25°C

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
V_{REF}	Internal reference (Adj.)	T_A = 25°C	0.796	0.8	0.804	V
V_{OUT}	Output voltage range	V_{IN} = 5 V, I_{OUT} = 1.5 A	V_{REF}		3.6	V
	Accuracy(1)	2.97 V ≤ V_{BIAS} ≤ 5.5 V, 50 mA ≤ I_{OUT} ≤ 1.5 A (Legacy Chip)	–2	±0.5	2	%
		2.97 V ≤ V_{BIAS} ≤ 5.5 V, 50 mA ≤ I_{OUT} ≤ 1.5 A (New Chip)	–1	±0.3	1	
$\Delta V_{OUT\ (\Delta VIN)}$	Line regulation	$V_{OUT(nom)}$ + 0.3 ≤ V_{IN} ≤ 5.5 V (Legacy Chip)		0.03		%/V
		$V_{OUT(nom)}$ + 0.3 ≤ V_{IN} ≤ 5.5 V (New Chip)		0.001		
$\Delta V_{OUT\ (\Delta IOUT)}$	Load regulation	50 mA ≤ I_{OUT} ≤ 1.5 A		0.09		%/A
V_{DO}	V_{IN} dropout voltage(2)	I_{OUT} = 1.5 A, V_{BIAS} – $V_{OUT(nom)}$ ≥ 3.25 V (Legacy Chip) (3)		60	165	mV
		I_{OUT} = 1.5 A, V_{BIAS} – $V_{OUT(nom)}$ ≥ 3.25 V (New Chip) (3)		50	100	
	V_{BIAS} dropout voltage(2)	I_{OUT} = 1.5 A, V_{IN} = V_{BIAS} (Legacy Cip)		1.31	1.6	V
		I_{OUT} = 1.5 A, V_{IN} = V_{BIAS} (New Chip)		1.31	1.43	
I_{CL}	Output current limit	V_{OUT} = 80% × $V_{OUT(nom)}$	2		5.5	A
I_{BIAS}	BIAS pin current	(Legacy Chip)		1	2	mA
		(New Chip)		1	1.2	
I_{SHDN}	Shutdown supply current (I_{GND})	V_{EN} ≤ 0.4 V (Legacy Chip)		1	50	µA
		V_{EN} ≤ 0.4 V (New Chip)		0.85	2.75	
I_{FB}	Feedback pin current	(Legacy Chip)	–1	0.15	1	µA
		(New Chip)	–30	0.15	30	nA
PSRR	Power-supply rejection (V_{IN} to V_{OUT})	1 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V		60		dB
		300 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V		30		
	Power-supply rejection (V_{BIAS} to V_{OUT})	1 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V (Legacy Chip)		50		
		1 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V (New Chip)		59		
		300 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V (Legacy Chip)		30		
		300 kHz, I_{OUT} = 1.5 A, V_{IN} = 1.8 V, V_{OUT} = 1.5 V (New Chip)		50		
V_n	Output noise voltage	BW = 100 Hz to 100 kHz, I_{OUT} = 1.5 A, C_{SS} = 1 nF (Legacy Chip)		25 × V_{OUT}		µVrms
		BW = 100 Hz to 100 kHz, I_{OUT} = 1.5 A, C_{SS} = 1 nF (New Chip)		20 × V_{OUT}		
t_{STR}	Minimum startup time	R_{LOAD} for I_{OUT} = 1.0 A, C_{SS} = open (Legacy Chip)		200		µs
		R_{LOAD} for I_{OUT} = 1.0 A, C_{SS} = open (New Chip)		250		
I_{SS}	Soft-start charging current	V_{SS} = 0.4 V (Legacy Chip)		440		nA
		V_{SS} = 0.4 V (New Chip)		530		
$V_{EN(hi)}$	Enable input high level		1.1		5.5	V
$V_{EN(lo)}$	Enable input low level		0		0.4	V
$V_{EN(hys)}$	Enable pin hysteresis	(Legacy Chip)		50		mV
		(New Chip)		55		
$V_{EN(dg)}$	Enable pin deglitch time			20		µs

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5.5 Electrical Characteristics (continued)

at V_{EN} = 1.1 V, V_{IN} = V_{OUT} + 0.3 V, C_{BIAS} = 0.1 µF, C_{IN} = C_{OUT} = 10 µF, C_{NR} = 1 nF, I_{OUT} = 50 mA, V_{BIAS} = 5.0 V, and T_J = –40°C to 125°C (unless otherwise noted); typical values are at T_J = 25°C

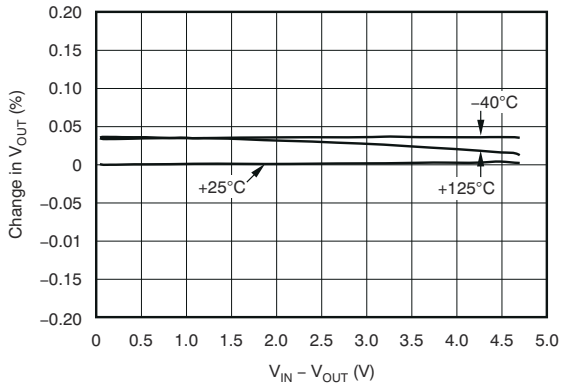
PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
I_{EN}	Enable pin current	V_{EN} = 5 V (Legacy Chip)		0.1	1	µA
		V_{EN} = 5 V (New Chip)		0.1	0.3	
V_{IT}	PG trip threshold	V_{OUT} decreasing	85	90	94	$\%V_{OUT}$
V_{HYS}	PG trip hysteresis			3		$\%V_{OUT}$
$V_{PG(lo)}$	PG output low voltage	I_{PG} = 1 mA (sinking), V_{OUT} < V_{IT} (Legacy Chip)			0.3	V
		I_{PG} = 1 mA (sinking), V_{OUT} < V_{IT} (New Chip)			0.125	
$I_{PG(lkg)}$	PG leakage current	V_{PG} = 5.25 V, V_{OUT} > V_{IT} (Legacy Chip)		0.1	1	µA
		V_{PG} = 5.25 V, V_{OUT} > V_{IT} (New Chip)		0.001	0.05	
T_{SD}	Thermal shutdown temperature	Shutdown, temperature increasing		165		℃
		Reset, temperature decreasing		140		
$R_{PULLDOWN}$	Output pulldown resitance	V_{BIAS} = 5V, V_{EN} = 0V		0.83	1	kΩ

(1) Adjustable devices tested at 0.8 V; resistor tolerance is not taken into account.
(2) Dropout is defined as the voltage from V_{IN} to V_{OUT} when V_{OUT} is 3% below nominal.
(3) 3.25 V is a test condition of this device and can be adjusted by referring to Figure 5-11.

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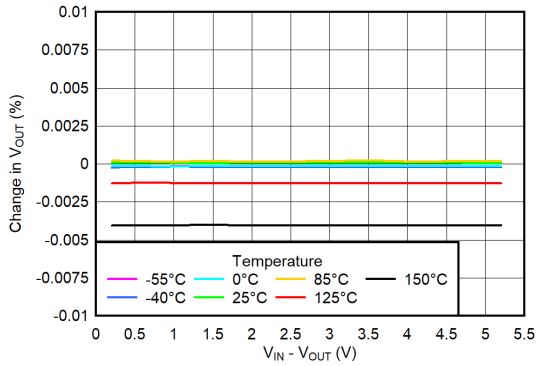
5.6 Typical Characteristics: I_{OUT} = 50 mA

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



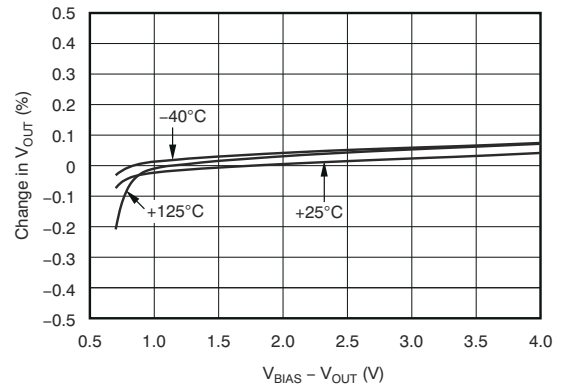
Legacy chip

Figure 5-1. V_{IN} Line Regulation



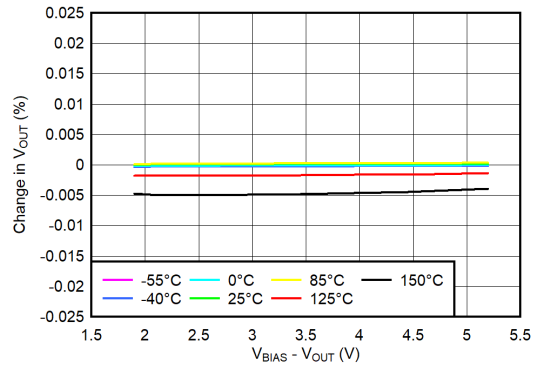
New chip

Figure 5-2. V_{IN} Line Regulation



Legacy chip

Figure 5-3. V_{BIAS} Line Regulation



New chip

Figure 5-4. V_{BIAS} Line Regulation

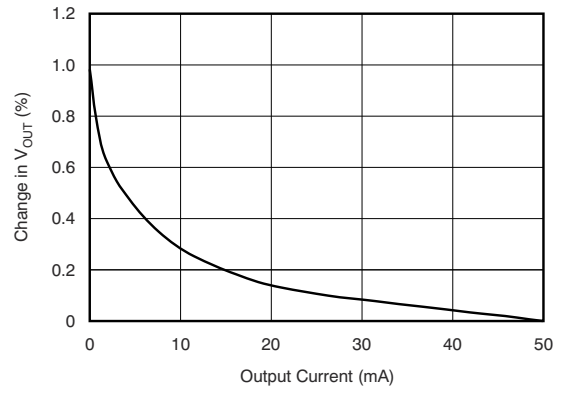
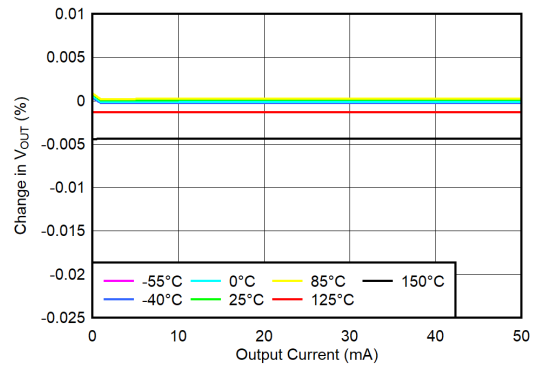


Figure 5-5. Load Regulation at Light Load



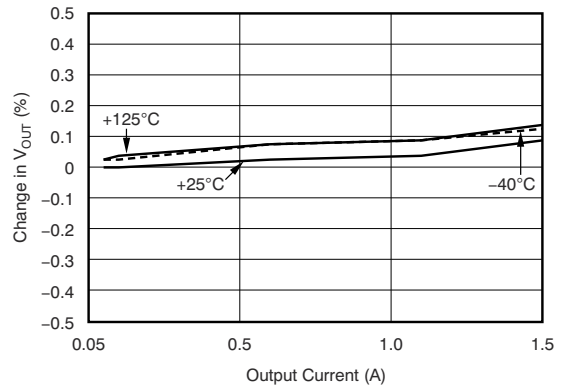
New chip

Figure 5-6. Load Regulation at Light Load

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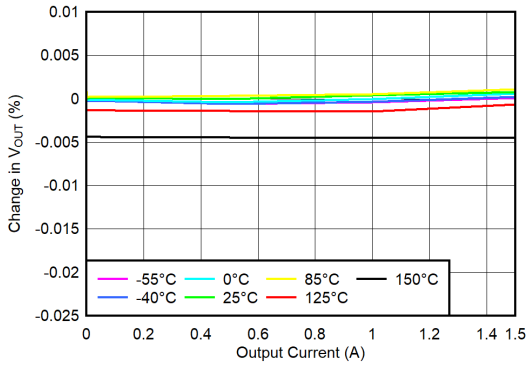
5.6 Typical Characteristics: I_{OUT} = 50 mA (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



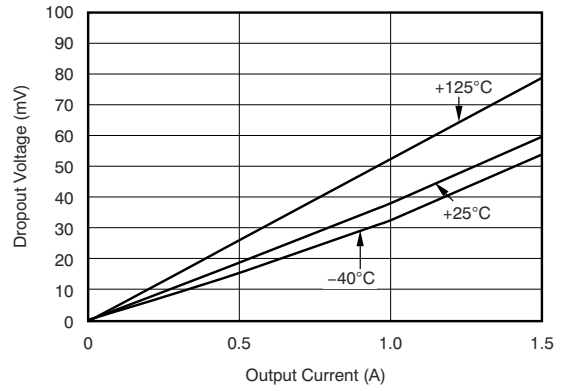
Legacy chip

Figure 5-7. Load Regulation



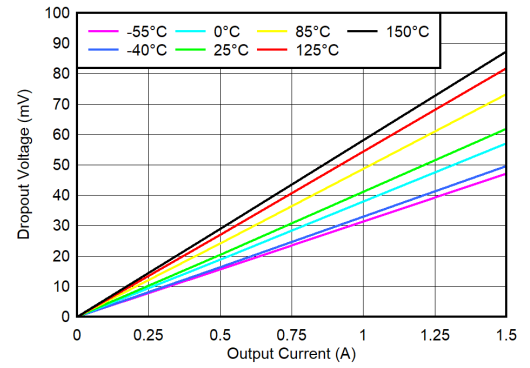
New chip

Figure 5-8. Load Regulation



Legacy chip

Figure 5-9. V_{IN} Dropout Voltage vs I_{OUT} and Temperature (T_J)



New chip

Figure 5-10. V_{IN} Dropout Voltage vs I_{OUT} and Temperature (T_J)

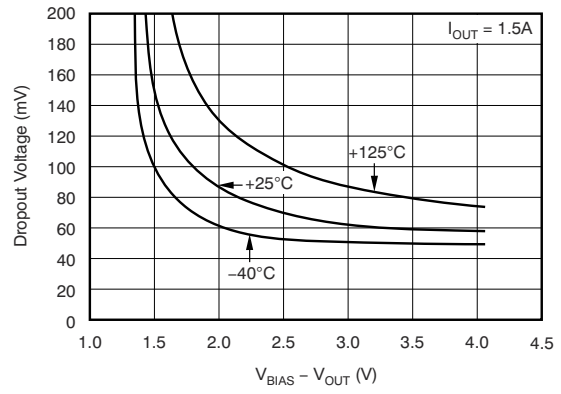


Figure 5-11. V_{IN} Dropout Voltage vs (V_{BIAS} – V_{OUT}) and Temperature (T_J)

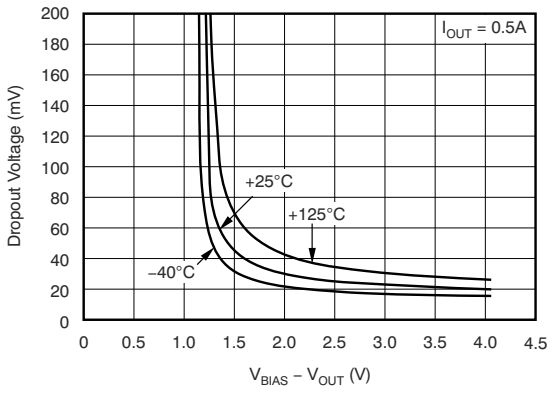
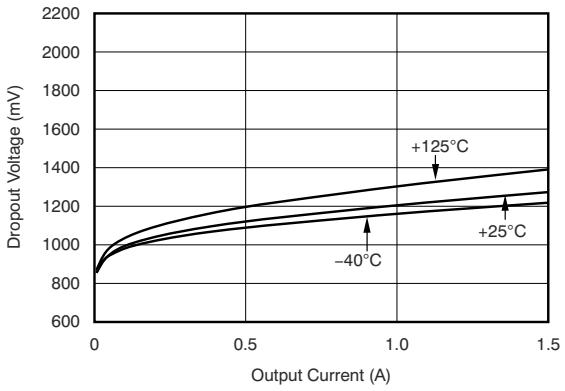


Figure 5-12. V_{IN} Dropout Voltage vs (V_{BIAS} – V_{OUT}) and Temperature (T_J)

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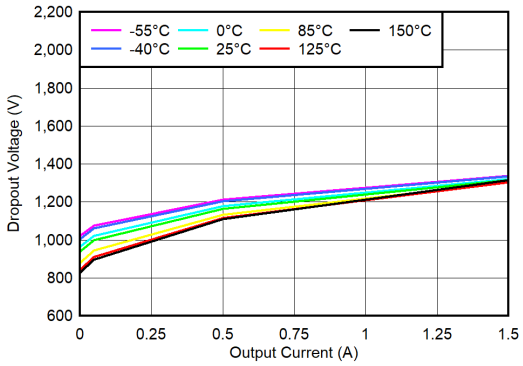
5.6 Typical Characteristics: I_{OUT} = 50 mA (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



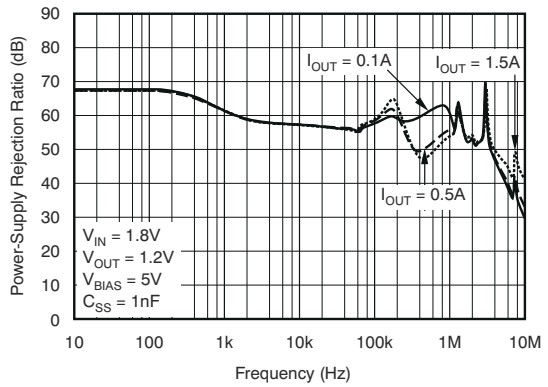
Legacy chip

Figure 5-13. V_{BIAS} Dropout Voltage vs I_{OUT} and Temperature (T_J)



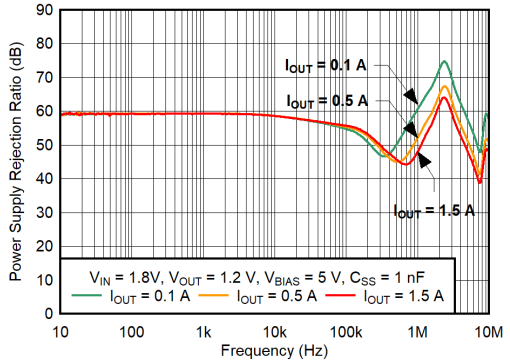
New chip

Figure 5-14. V_{BIAS} Dropout Voltage vs I_{OUT} and Temperature (T_J)



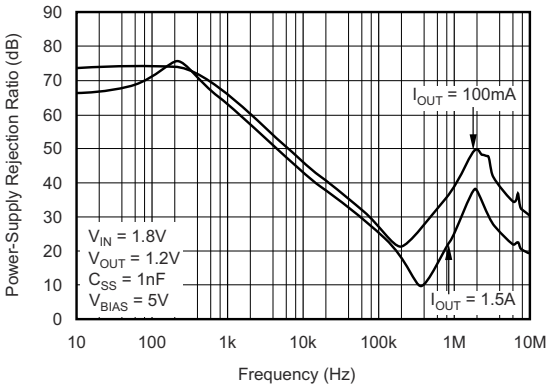
Legacy chip

Figure 5-15. V_{BIAS} PSRR vs Frequency



New chip

Figure 5-16. V_{BIAS} PSRR vs Frequency



Legacy chip

Figure 5-17. V_{IN} PSRR vs Frequency

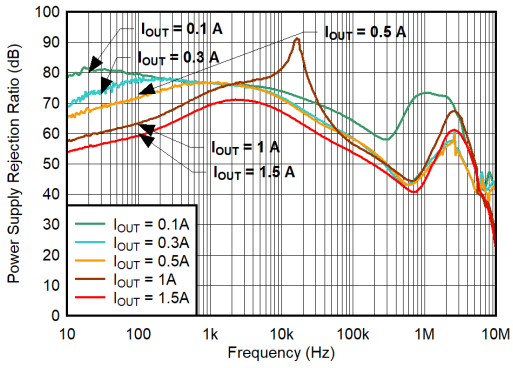
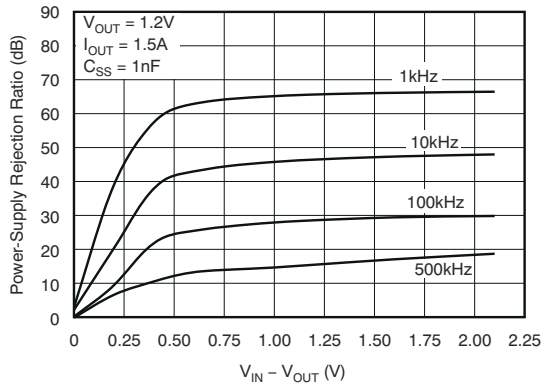


Figure 5-18. V_{IN} PSRR vs Frequency

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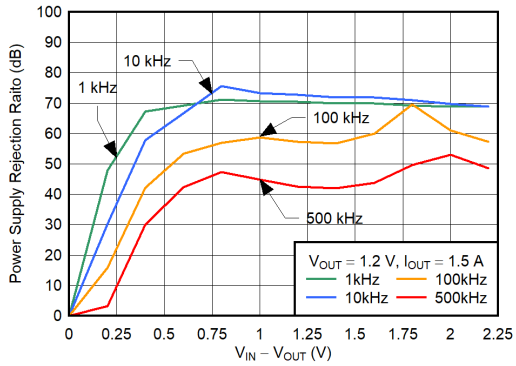
5.6 Typical Characteristics: I_{OUT} = 50 mA (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



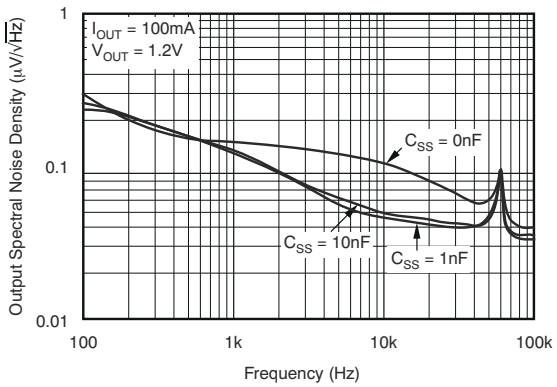
Legacy chip

Figure 5-19. V_{IN} PSRR vs (V_{IN} – V_{OUT})



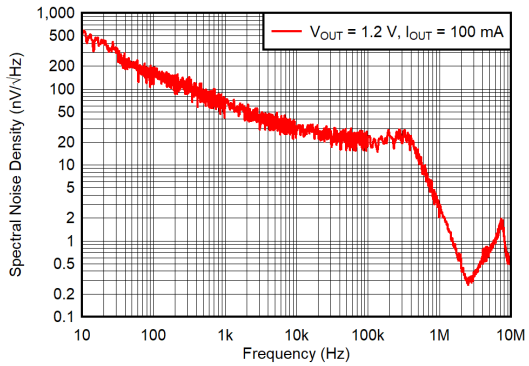
New chip

Figure 5-20. V_{IN} PSRR vs (V_{IN} – V_{OUT})



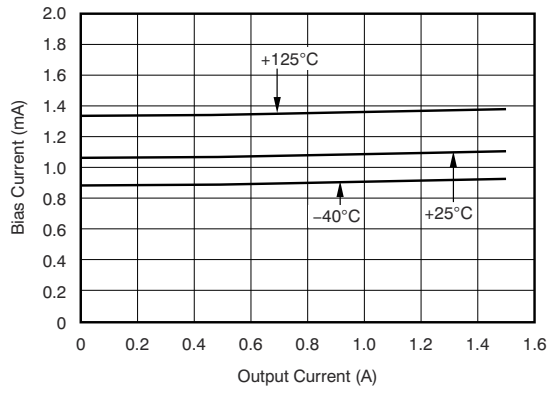
Legacy chip

Figure 5-21. Noise Spectral Density



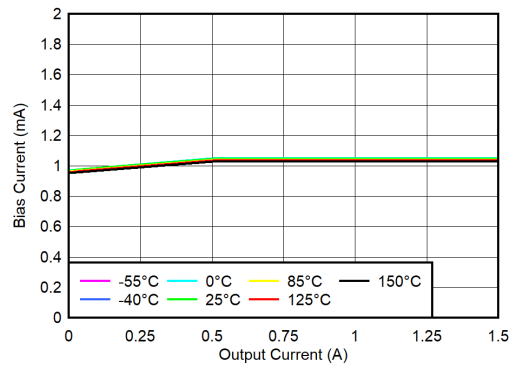
New chip

Figure 5-22. Noise Spectral Density



Legacy chip

Figure 5-23. BIAS Pin Current vs Output Current and Temperature (T_J)



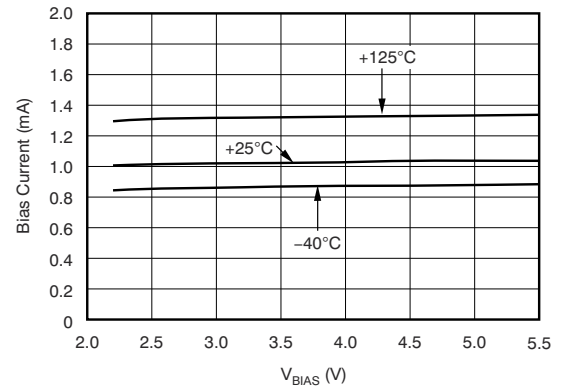
New chip

Figure 5-24. BIAS Pin Current vs Output Current and Temperature (T_J)

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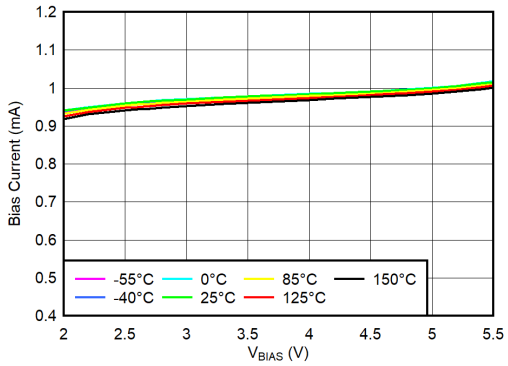
5.6 Typical Characteristics: I_{OUT} = 50 mA (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



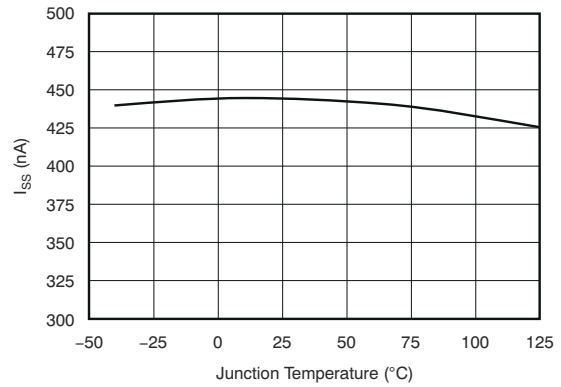
Legacy chip

Figure 5-25. BIAS Pin Current vs V_{BIAS} and Temperature (T_J)



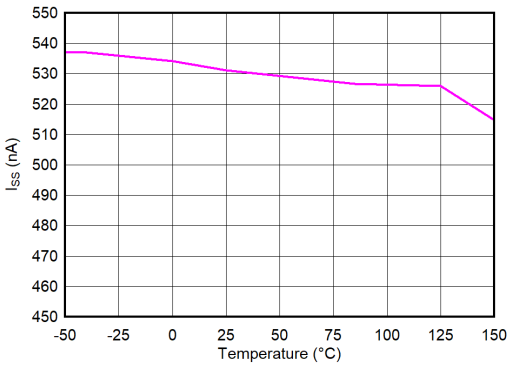
New chip

Figure 5-26. BIAS Pin Current vs V_{BIAS} and Temperature (T_J)



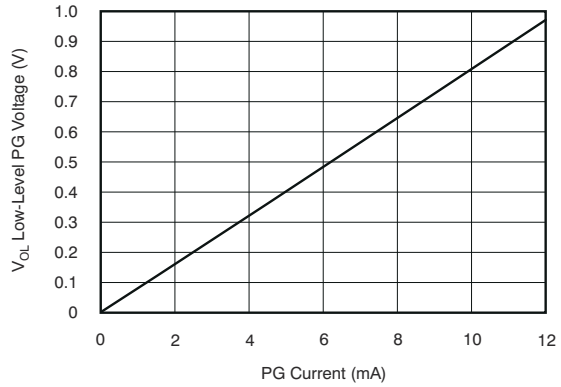
Legacy chip

Figure 5-27. Soft-Start Charging Current (I_{SS}) vs Temperature (T_J)



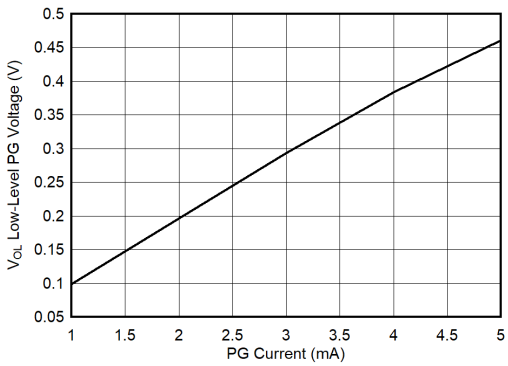
New chip

Figure 5-28. Soft-Start Charging Current (I_{SS}) vs Temperature (T_J)



Legacy chip

Figure 5-29. Low-Level PG Voltage vs Current



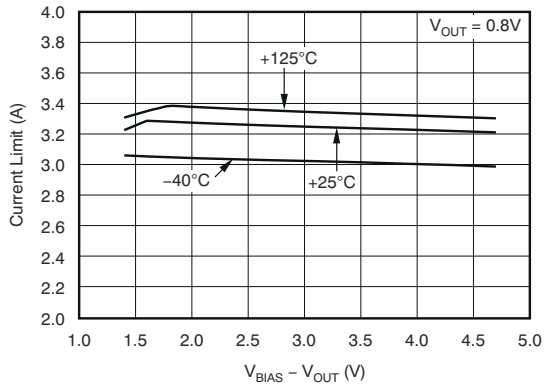
New chip

Figure 5-30. Low-Level PG Voltage vs Current

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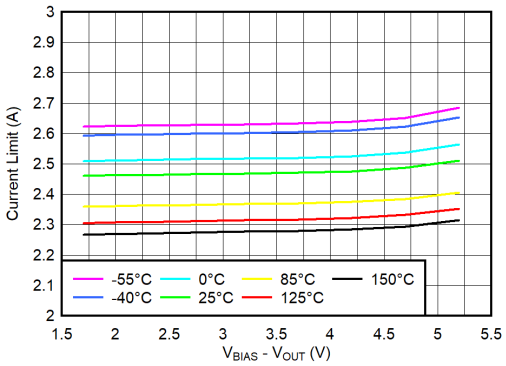
5.6 Typical Characteristics: I_{OUT} = 50 mA (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 50 mA, V_{EN} = V_{IN}, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



Legacy chip

Figure 5-31. Current Limit vs (V_{BIAS} – V_{OUT})



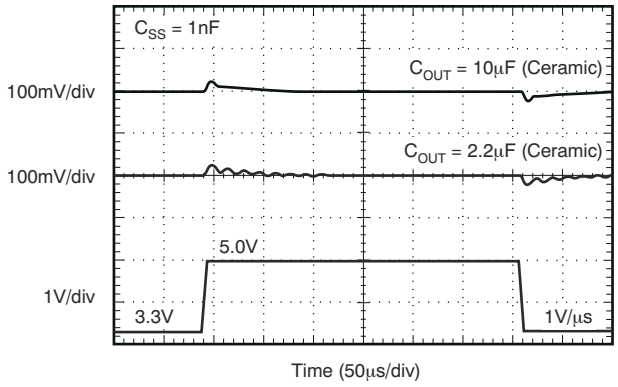
New chip

Figure 5-32. Current Limit vs (V_{BIAS} – V_{OUT})

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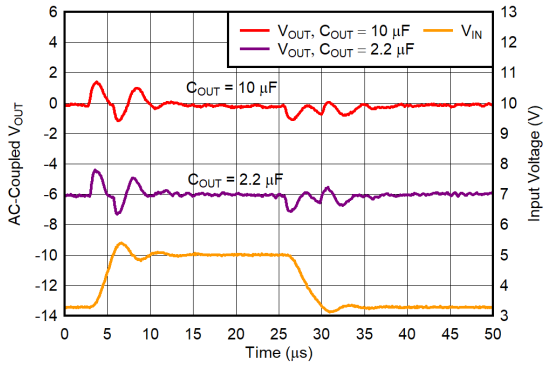
5.7 Typical Characteristics: I_{OUT} = 1 A

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 1 A, V_{EN} = V_{IN} = 1.8 V, V_{OUT} = 1.5 V, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



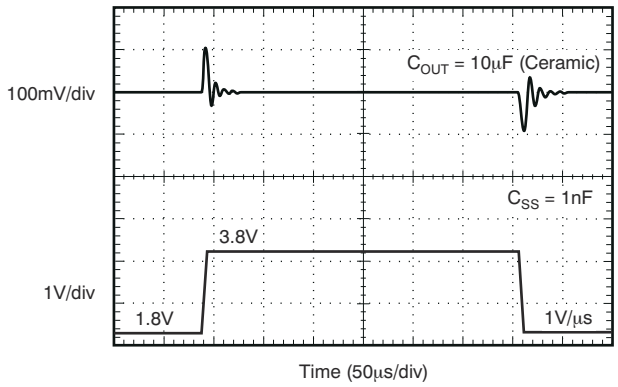
Legacy chip

Figure 5-33. V_{BIAS} Line Transient



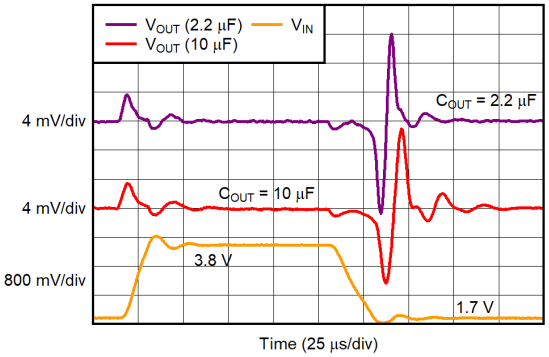
New chip

Figure 5-34. V_{BIAS} Line Transient



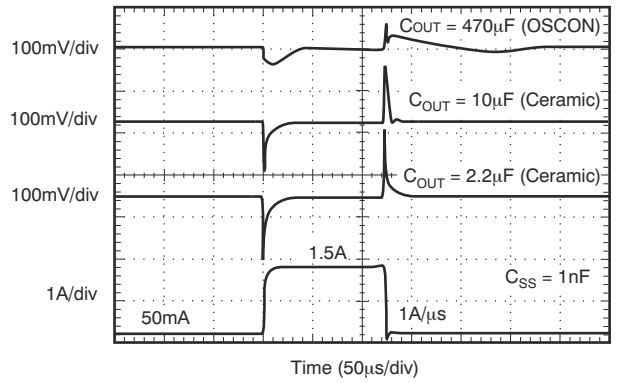
Legacy chip

Figure 5-35. V_{IN} Line Transient



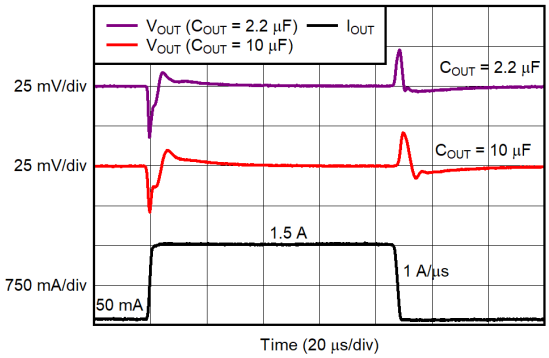
New chip

Figure 5-36. V_{IN} Line Transient



Legacy chip

Figure 5-37. Output Load Transient Response



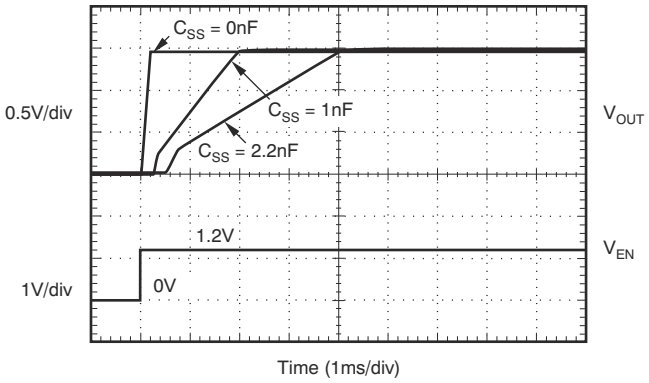
New chip

Figure 5-38. Output Load Transient Response

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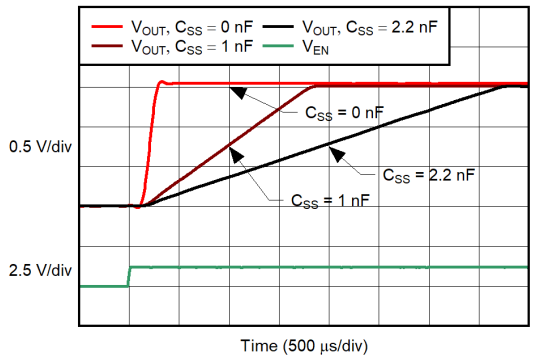
5.7 Typical Characteristics: I_{OUT} = 1 A (continued)

at T_J = 25°C, V_{IN} = $V_{OUT(nom)}$ + 0.3 V, V_{BIAS} = 5 V, I_{OUT} = 1 A, V_{EN} = V_{IN} = 1.8 V, V_{OUT} = 1.5 V, C_{IN} = 1 µF, C_{BIAS} = 4.7 µF, and C_{OUT} = 10 µF (unless otherwise noted)



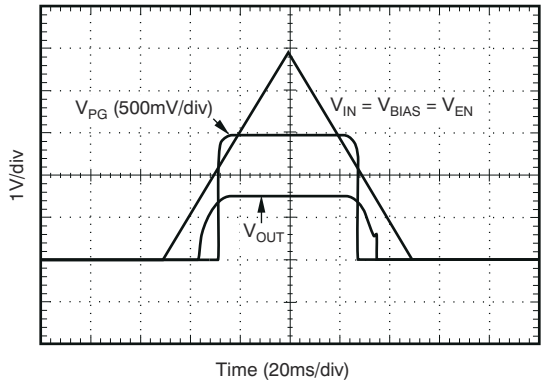
Legacy chip

Figure 5-39. Turn-On Response



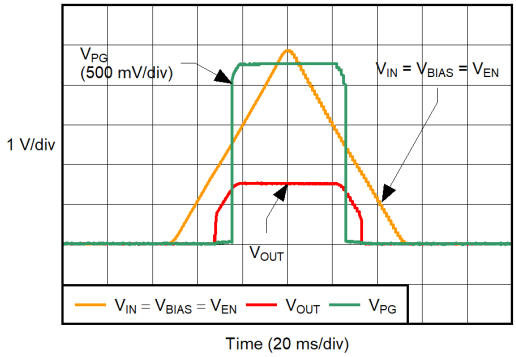
New chip

Figure 5-40. Turn-On Response



Legacy chip

Figure 5-41. Power-Up, Power-Down



New chip

Figure 5-42. Power-Up, Power-Down

6 Detailed Description

6.1 Overview

The TPS748 is a low-dropout regulator that features soft-start capability. This regulator uses a low current bias input to power all internal control circuitry, allowing the NMOS pass transistor to regulate very low input and output voltages.

The use of an NMOS-pass transistor offers several critical advantages for many applications. Unlike a PMOS topology device, the output capacitor has little effect on loop stability. This architecture allows the TPS748 to be stable with any capacitor type of value 2.2 µF or greater. Transient response is also superior to PMOS topologies, particularly for low V_{IN} applications.

The TPS748 features a programmable voltage-controlled soft-start circuit that provides a smooth, monotonic start-up and limits start-up inrush currents that may be caused by large capacitive loads. A power-good (PG) output is available to allow supply monitoring and sequencing of other supplies. An enable (EN) pin with hysteresis and deglitch allows slow-ramping signals to be used for sequencing the device. The low V_{IN} and V_{OUT} capability allows for inexpensive, easy-to-design, and efficient linear regulation between the multiple supply voltages often required by processor-intensive systems.

6.2 Functional Block Diagrams

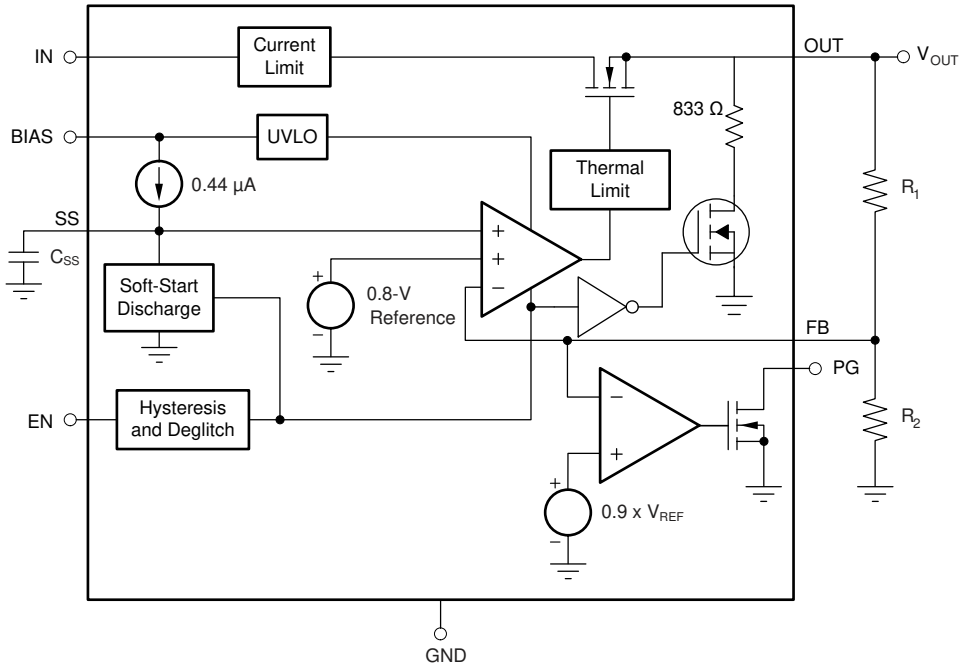


Figure 6-1. Legacy Chip Functional Block Diagram

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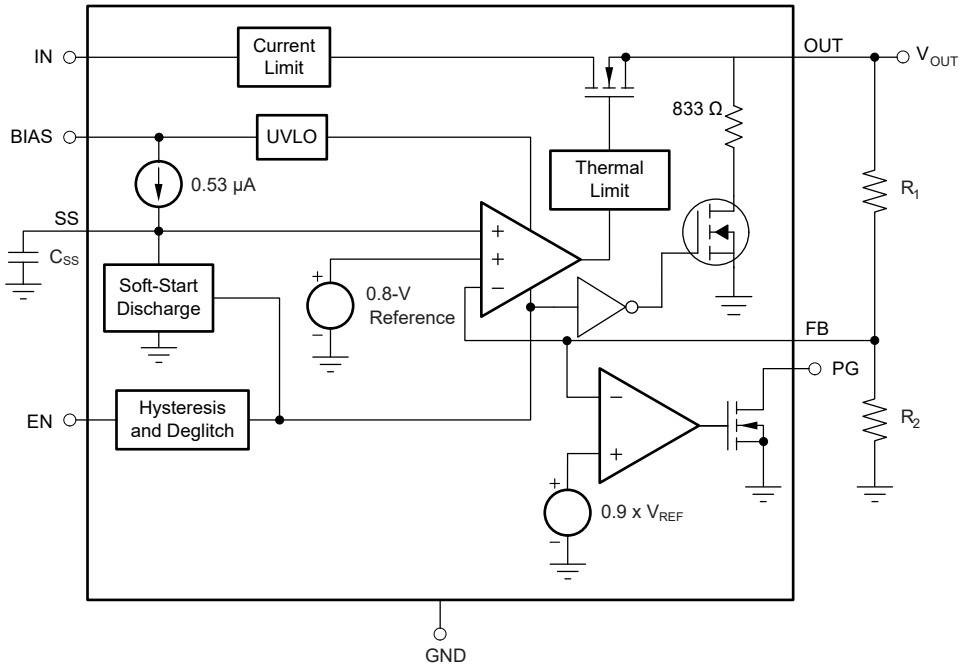


Figure 6-2. New Chip Functional Block Diagram

6.3 Feature Description

6.3.1 Enable/Shutdown

The enable (EN) pin is active high and is compatible with standard digital signaling levels. V_{EN} below 0.4 V turns the regulator off, while V_{EN} above 1.1 V turns the regulator on. Unlike many regulators, the enable circuitry has hysteresis and deglitching for use with relatively slowly ramping analog signals. This configuration allows the TPS748 to be enabled by connecting the output of another supply to the EN pin. The enable circuitry typically has 50 mV of hysteresis and a deglitch circuit to help avoid on-off cycling as a result of small glitches in the V_{EN} signal.

The enable threshold is typically 0.8 V and varies with temperature and process variations. Temperature variation is approximately –1 mV/°C; process variation accounts for most of the rest of the variation to the 0.4-V and 1.1-V limits. If precise turn-on timing is required, a fast rise-time signal must be used to enable the TPS748.

If not used, EN can be connected to either IN or BIAS. If EN is connected to IN, connect this pin as close as possible to the largest capacitance on the input to prevent voltage droops on that line from triggering the enable circuit.

The TPS748 has an internal active pulldown circuit that connects the output to GND through an 833-Ω resistor when the device is disabled. This resistor discharges the output with a time constant of:

$$\tau = \left(\frac{833 \times R_L}{833 + R_L} \right) \times C_{OUT} \tag{1}$$

6.3.2 Power Good

The power-good (PG) pin is an open-drain output and can be connected to any 5.5-V or lower rail through an external pullup resistor. This pin requires at least 1.1 V on V_{BIAS} in order to have a valid output. The PG output is high-impedance when V_{OUT} is greater than V_{IT} + V_{HYS}. If V_{OUT} drops below V_{IT} or if V_{BIAS} drops below 1.9 V, the open-drain output turns on and pulls the PG output low. The PG pin also asserts when the device is disabled. The recommended operating condition of PG pin sink current is up to 1 mA, so the pullup resistor for PG must be in the range of 10 kΩ to 1 MΩ. If output voltage monitoring is not needed, the PG pin can be left floating.

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6.3.3 Internal Current Limit

The TPS748 features a factory-trimmed current limit that is flat over temperature and supply voltage. The current limit allows the device to supply surges of up to 2 A and maintain regulation. The current limit responds in approximately 10 µs to reduce the current during a short-circuit fault.

The internal current limit protection circuitry of the TPS748 is designed to protect against overload conditions. This circuitry is not intended to allow operation above the rated current of the device. Continuously running the TPS748 above the rated current degrades device reliability.

6.3.4 Thermal Protection

Thermal protection disables the output when the junction temperature rises to approximately 160°C, allowing the device to cool. When the junction temperature cools to approximately 140°C, the output circuitry is enabled. Depending on power dissipation, thermal resistance, and ambient temperature the thermal protection circuit can cycle on and off. This cycling limits the dissipation of the regulator, protecting the regulator from damage as a result of overheating.

Activation of the thermal protection circuit indicates excessive power dissipation or inadequate heat sinking. For reliable operation, limit junction temperature to 125°C maximum. To estimate the margin of safety in a complete design (including heat sink), increase the ambient temperature until thermal protection is triggered; use worst-case loads and signal conditions. For good reliability, thermal protection must trigger at least 40°C above the maximum expected ambient condition of the application. This condition produces a worst-case junction temperature of 125°C at the highest expected ambient temperature and worst-case load.

The internal protection circuitry of the TPS748 is designed to protect against overload conditions. This circuitry is not intended to replace proper heat sinking. Continuously running the TPS748 into thermal shutdown degrades device reliability.

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6.4 Device Functional Modes

Table 6-1 shows the conditions that lead to the different modes of operation.

Table 6-1. Device Functional Mode Comparison

OPERATING MODE	PARAMETER				
	V_{IN}	V_{EN}	V_{BIAS}	I_{OUT}	T_J
Normal mode	$V_{IN} > V_{OUT(nom)} + V_{DO}$ (V_{IN})	$V_{EN} > V_{EN(high)}$	$V_{BIAS} \geq V_{OUT} + 1.6$ V	$I_{OUT} < I_{CL}$	$T_J < 125°C$
Dropout mode	$V_{IN} < V_{OUT(nom)} + V_{DO}$ (V_{IN})	$V_{EN} > V_{EN(high)}$	$V_{BIAS} < V_{OUT} + 1.6$ V	—	$T_J < 125°C$
Disabled mode (any true condition disables the device)	$V_{IN} < V_{IN(min)}$	$V_{EN} < V_{EN(low)}$	$V_{BIAS} < V_{BIAS(min)}$	—	$T_J > 165°C$

6.4.1 Normal Operation

The device regulates to the nominal output voltage under the following conditions:

- The input voltage and bias voltage are both at least at the respective minimum specifications
- The enable voltage has previously exceeded the enable rising threshold voltage and has not decreased below the enable falling threshold
- The output current is less than the current limit
- The device junction temperature is less than the maximum specified junction temperature

6.4.2 Dropout Operation

If the input voltage is lower than the nominal output voltage plus the specified dropout voltage, but all other conditions are met for normal operation, the device operates in dropout mode. In this condition, the output voltage is the same as the input voltage minus the dropout voltage. The transient performance of the device is significantly degraded because the pass transistor is in a triode state and no longer controls the current through the LDO. Line or load transients in dropout can result in large output voltage deviations.

6.4.3 Disabled

The device is disabled under the following conditions:

- The input or bias voltages are below the respective minimum specifications
- The enable voltage is less than the enable falling threshold voltage or has not yet exceeded the enable rising threshold
- The device junction temperature is greater than the thermal shutdown temperature

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6.5 Programming

6.5.1 Programmable Soft-Start

The TPS74801 features a programmable, monotonic, voltage-controlled soft-start that is set with an external capacitor (C_{SS}). This feature is important for many applications because soft-start eliminates power-up initialization problems when powering FPGAs, DSPs, or other processors. The controlled voltage ramp of the output also reduces peak inrush current during start-up, minimizing start-up transient events to the input power bus.

To achieve a linear and monotonic soft-start, the TPS74801 error amplifier tracks the voltage ramp of the external soft-start capacitor until the voltage exceeds the internal reference. The soft-start ramp time depends on the soft-start charging current (I_{SS}), soft-start capacitance (C_{SS}), and the internal reference voltage (V_{REF}), and can be calculated using Equation 2:

$$t_{SS} = \frac{(V_{REF} \times C_{SS})}{I_{SS}} \quad (2)$$

If large output capacitors are used, the device current limit (I_{CL}) and the output capacitor can set the start-up time. In this case, the start-up time is given by Equation 3:

$$t_{SSCL} = \frac{(V_{OUT(NOM)} \times C_{OUT})}{I_{CL(MIN)}} \quad (3)$$

where:

- $V_{OUT(nom)}$ is the nominal output voltage
- C_{OUT} is the output capacitance
- $I_{CL(min)}$ is the minimum current limit for the device

In applications where monotonic start up is required, the soft-start time given by Equation 2 must be set greater than Equation 3.

The maximum recommended soft-start capacitor is 15 nF. Larger soft-start capacitors can be used and do not damage the device; however, the soft-start capacitor discharge circuit can possibly be unable to fully discharge the soft-start capacitor when enabled. Soft-start capacitors larger than 15 nF can be a problem in applications where the enable pin must be rapidly pulsed and with the device still required to soft-start from ground. C_{SS} must be low-leakage; X7R, X5R, or C0G dielectric materials are preferred. See Table 6-2 for suggested soft-start capacitor values.

Table 6-2. Standard Capacitor Values for Programming the Soft-Start Time

C_{SS}	SOFT-START TIME(1) (Legacy Chip)	SOFT-START TIME(1) (New Chip)
Open	0.1 ms	0.25ms
270 pF	0.5 ms	0.4ms
560 pF	1 ms	0.8ms
2.7 nF	5 ms	4.1ms
5.6 nF	10 ms	8.5ms
10 nF	18 ms	15ms

(1) $t_{SS}(s) = 0.8 \times C_{SS}(F) / I_{SS}$, where $t_{SS}(s)$ = soft-start time in seconds.

Another option to set the start-up rate is to use a feedforward capacitor; see the *Pros and Cons of Using a Feedforward Capacitor with a Low-Dropout Regulator* application note for more information.

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6.5.2 Sequencing Requirements

V_{IN}, V_{BIAS}, and V_{EN} can be sequenced in any order without causing damage to the device. However, for the soft-start function to work as intended, certain sequencing rules must be applied. Connecting EN to IN is acceptable for most applications, as long as V_{IN} is greater than 1.1 V and the ramp rate of V_{IN} and V_{BIAS} is faster than the set soft-start ramp rate.

There are several different start-up responses that are possible, but not typical:

- If the ramp rate of the input sources is slower than the set soft-start time, the output tracks the slower supply minus the dropout voltage until reaching the set output voltage
- If EN is connected to BIAS, the device soft-starts as programmed, provided that V_{IN} is present before V_{BIAS}
- If V_{BIAS} and V_{EN} are present before V_{IN} is applied and the set soft-start time has expired, then V_{OUT} tracks V_{IN}
- If the soft-start time has not expired, the output tracks V_{IN} until V_{OUT} reaches the value set by the charging soft-start capacitor

Figure 6-3 shows the use of an RC-delay circuit to hold off V_{EN} until V_{BIAS} has ramped. This technique can also be used to drive EN from V_{IN}. An external control signal can also be used to enable the device after V_{IN} and V_{BIAS} are present.

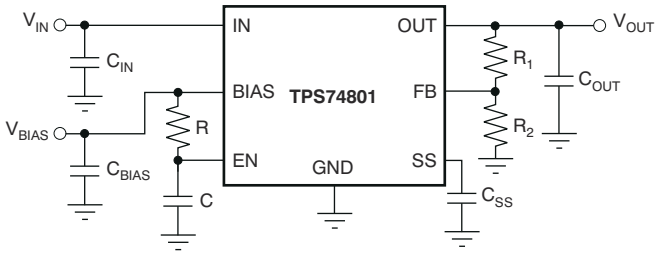


Figure 6-3. Soft-Start Delay Using an RC Circuit to Enable the Device

7 Application and Implementation

Note

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

7.1 Application Information

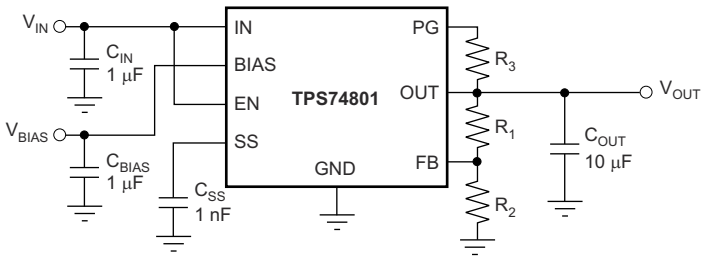
The TPS748 is a low-dropout regulator that features soft-start capability. This regulator uses a low current bias input to power all internal control circuitry, allowing the NMOS pass transistor to regulate very low input and output voltages.

The use of an NMOS-pass transistor offers several critical advantages for many applications. Unlike a PMOS topology device, the output capacitor has little effect on loop stability. This architecture allows the TPS748 to be stable with any capacitor type of value 2.2 µF or greater. Transient response is also superior to PMOS topologies, particularly for low V_{IN} applications.

The TPS748 features a programmable voltage-controlled soft-start circuit that provides a smooth, monotonic start-up and limits start-up inrush currents that can be caused by large capacitive loads. A power-good (PG) output is available to allow supply monitoring and sequencing of other supplies. An enable (EN) pin with hysteresis and deglitch allows slow-ramping signals to be used for sequencing the device. The low V_{IN} and V_{OUT} capability allows for inexpensive, easy-to-design, and efficient linear regulation between the multiple supply voltages often required by processor-intensive systems.

7.1.1 Adjusting the Output Voltage

Figure 7-1 shows the typical application circuit for the TPS748 adjustable output device.



$$V_{OUT} = 0.8 \times \left(1 + \frac{R_1}{R_2}\right)$$

Figure 7-1. Typical Application Circuit for the TPS748 (Adjustable)

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R_1 and R_2 can be calculated for any output voltage using the formula shown in Figure 7-1. Table 7-1 lists sample resistor values of common output voltages. In order to achieve the maximum accuracy specifications, R_2 must be ≤ 4.99 kΩ.

Table 7-1. Standard 1% Resistor Values for Programming the Output Voltage(1)

R_1 (kΩ)	R_2 (kΩ)	V_{OUT} (V)
Short	Open	0.8
0.619	4.99	0.9
1.13	4.53	1.0
1.37	4.42	1.05
1.87	4.99	1.1
2.49	4.99	1.2
4.12	4.75	1.5
3.57	2.87	1.8
3.57	1.69	2.5
3.57	1.15	3.3

(1) $V_{OUT} = 0.8 \times (1 + R_1 / R_2)$.

Note

When V_{BIAS} and V_{EN} are present and V_{IN} is not supplied, this device outputs approximately 50 µA of current from OUT. Although this condition does not cause any damage to the device, the output current can charge up the OUT node if total resistance between OUT and GND (including external feedback resistors) is greater than 10 kΩ.

7.1.2 Input, Output, and Bias Capacitor Requirements

The device is designed to be stable for all available types and values of output capacitors ≥ 2.2 µF. The device is also stable with multiple capacitors in parallel, which can be of any type or value.

The capacitance required on the IN and BIAS pins strongly depends on the input supply source impedance. To counteract any inductance in the input, the minimum recommended capacitor for V_{IN} is 1 µF and minimum recommended capacitor for V_{BIAS} is 0.1 µF. If V_{IN} and V_{BIAS} are connected to the same supply, the recommended minimum capacitor for V_{BIAS} is 4.7 µF. Use good-quality, low-ESR capacitors on the input; ceramic X5R and X7R capacitors are preferred. Place these capacitors as close to the pins as possible for optimum performance.

7.1.3 Transient Response

The TPS748 was designed to have excellent transient response for most applications with a small amount of output capacitance. In some cases, the transient response can be limited by the transient response of the input supply. This limitation is especially true in applications where the difference between the input and output is less than 300 mV. In this case, adding additional input capacitance improves the transient response much more than just adding additional output capacitance does. With a solid input supply, adding additional output capacitance reduces undershoot and overshoot during a transient event; see Figure 5-37 in the *Typical Characteristics* section. Because the TPS748 is stable with output capacitors as low as 2.2 µF, many applications can then need very little capacitance at the LDO output. For these applications, local bypass capacitance for the powered device can be sufficient to meet the transient requirements of the application. This design reduces the total solution cost by avoiding the need to use expensive, high-value capacitors at the LDO output.

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7.1.4 Dropout Voltage

The TPS748 offers very low dropout performance, making the device designed for high-current, low V_{IN}, low V_{OUT} applications. The low dropout of the TPS748 allows the device to be used in place of a dc/dc converter and still achieve good efficiency. Equation 4 provides a quick estimate of the efficiency.

$$\text{Efficiency} \approx \frac{V_{OUT} \times I_{OUT}}{\left[V_{IN} \times (I_{IN} + I_Q)\right]} \approx \frac{V_{OUT}}{V_{IN}} \text{ at } I_{OUT} >> I_Q \tag{4}$$

This efficiency provides designers with the power architecture for their applications to achieve the smallest, simplest, and lowest cost solutions.

There are two different specifications for dropout voltage with the TPS748. The first specification (see Figure 7-2) is referred to as *V_{IN} dropout* and is used when an external bias voltage is applied to achieve low dropout. This specification assumes that V_{BIAS} is at least 3.25 V[1] above V_{OUT}, which is the case for V_{BIAS} when powered by a 5.0-V rail with 5% tolerance and with V_{OUT} = 1.5 V. If V_{BIAS} is higher than V_{OUT} +3.25 V[1], V_{IN} dropout is less than specified.[1]

The second specification (illustrated in Figure 7-8) is referred to as *V_{BIAS} dropout* and applies to applications where IN and BIAS are tied together. This option allows the device to be used in applications where an auxiliary bias voltage is not available or low dropout is not required. Dropout is limited by BIAS in these applications because V_{BIAS} provides the gate drive to the pass transistor; therefore, V_{BIAS} must be 1.6 V above V_{OUT}. Because of this usage, IN and BIAS tied together become a highly inefficient solution that can consume large amounts of power. Pay attention not to exceed the power rating of the device package.

7.1.5 Output Noise

The TPS748 provides low output noise when a soft-start capacitor is used. When the device reaches the end of the soft-start cycle, the soft-start capacitor serves as a filter for the internal reference. By using a 1-nF soft-start capacitor, the output noise is reduced by half and is typically 30 μV_{RMS} for a 1.2-V output (10 Hz to 100 kHz). Further increasing C_{SS} has little effect on noise. Because most of the output noise is generated by the internal reference, the noise is a function of the set output voltage. The RMS noise with a 1-nF soft-start capacitor is given in Equation 5:

$$V_N(\mu V_{RMS}) = 25\left(\frac{\mu V_{RMS}}{V}\right) \times V_{OUT}(V) \tag{5}$$

The low output noise of the TPS748 makes the device a good choice for powering transceivers, PLLs, or other noise-sensitive circuitry.

[1] 3.25 V is a test condition of this device and can be adjusted by referring to Figure 5-11.

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7.2 Typical Applications

7.2.1 FPGA I/O Supply at 1.5 V With a Bias Rail

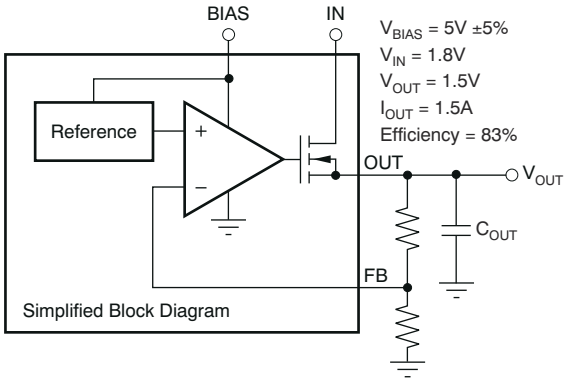


Figure 7-2. Typical Application of the TPS748 Using an Auxiliary Bias Rail

7.2.1.1 Design Requirements

This application powers the I/O rails of an FPGA , at $V_{OUT(nom)}$ = 1.5 V and $I_{OUT(dc)}$ = 1.5 A. The available external supply voltages are 1.8 V, 3.3 V, and 5 V.

7.2.1.2 Detailed Design Procedure

First, determine what supplies to use for the input and bias rails. A 1.8-V input can be stepped down to 1.5 V at 1.5 A if an external bias is provided, because the maximum dropout voltage is 165 mV if V_{BIAS} is at least 3.25 V higher than V_{OUT}. To achieve this voltage step, the bias rail is supplied by the 5-V supply. The approximation in Equation 4 estimates the efficiency at 83.3%.

The output voltage then must be set to 1.5 V. As Table 7-1 describes, set R_1 = 4.12 kΩ and R_2= 4.75 kΩ to obtain the required output voltage. The minimum capacitor sizing is desired to reduce the total solution size footprint; see the *Input, Output, and Bias Capacitor Requirements* section for C_{IN} = 1 µF, C_{BIAS} = 1 µF, and C_{OUT} = 2.2 µF. Use C_{SS} = 1 nF for a typical 1.8-ms start-up time.

Figure 7-2 shows a simplified version of the final circuit.

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7.2.1.3 Application Curves

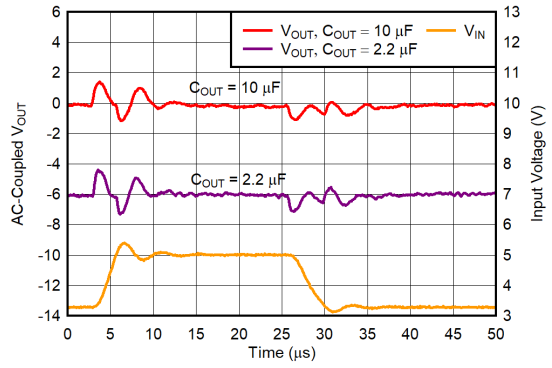


Figure 7-3. V_{BIAS} Line Transient

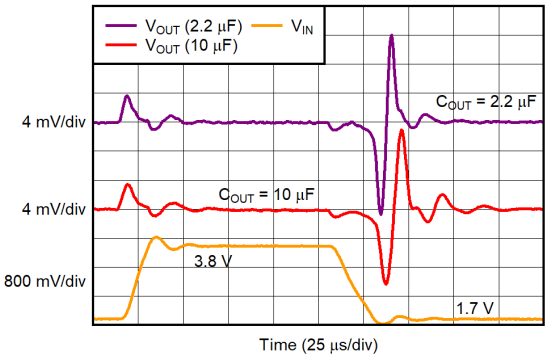


Figure 7-4. V_{IN} Line Transient

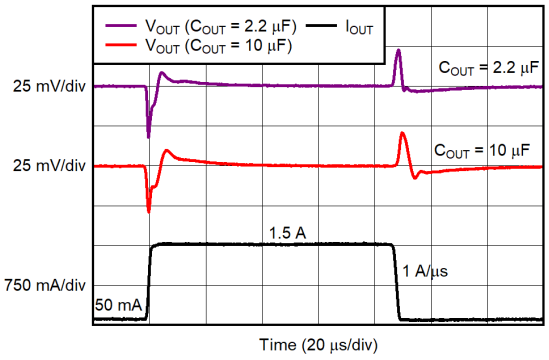


Figure 7-5. Output Load Transient Response

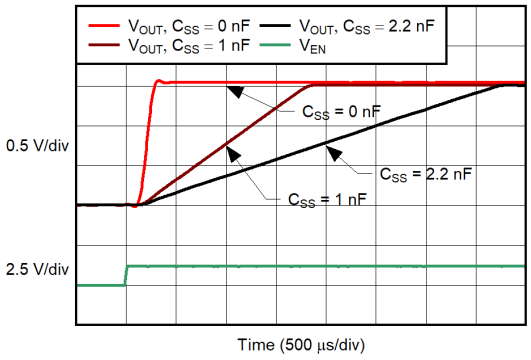


Figure 7-6. Turn-On Response

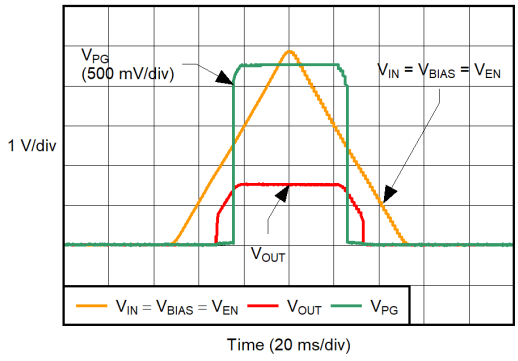


Figure 7-7. Power-Up, Power-Down

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7.2.2 FPGA I/O Supply at 1.5 V Without a Bias Rail

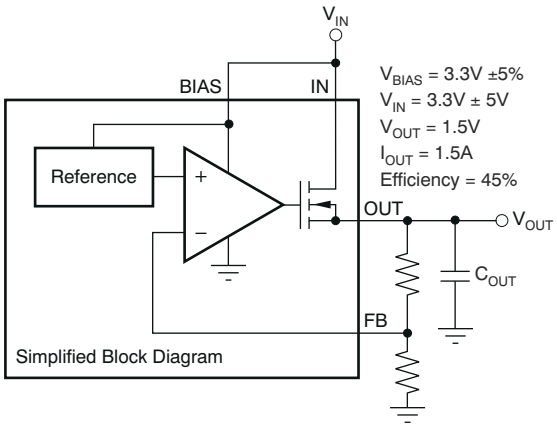


Figure 7-8. Typical Application of the TPS748 Without an Auxiliary Bias Rail

7.2.2.1 Design Requirements

The application powers the I/O rails of an FPGA, at $V_{OUT(nom)}$ = 1.5 V and $I_{OUT(max)}$ = 1.5 A. The only available rail is 3.3 V. The I/O pins are driven for only short durations with a 5% duty cycle, so thermal issues are not a concern.

7.2.2.2 Detailed Design Procedure

There is only one available rail; therefore, the input supply and the bias supply are connected together on the 3.3-V input supply.

The output voltage must be set to 1.5 V. As Table 7-1 describes, set R_1 = 4.12 kΩ and R_2 = 4.75 kΩ to obtain the required output voltage. The minimum capacitor sizing is desired to reduce the total solution size footprint; see the *Input, Output, and Bias Capacitor Requirements* section for C_{IN} = C_{BIAS} = 4.7 µF, and C_{OUT} = 2.2 µF. Use C_{SS} = 1 nF for a typical 1.8-ms start-up time.

Figure 7-8 shows the TPS748 configured without a bias rail.

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7.2.2.3 Application Curves

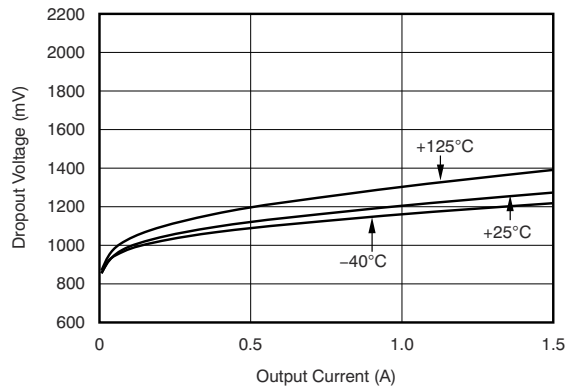


Figure 7-9. V_{BIAS} Dropout Voltage vs I_{OUT} and Temperature (T_J)

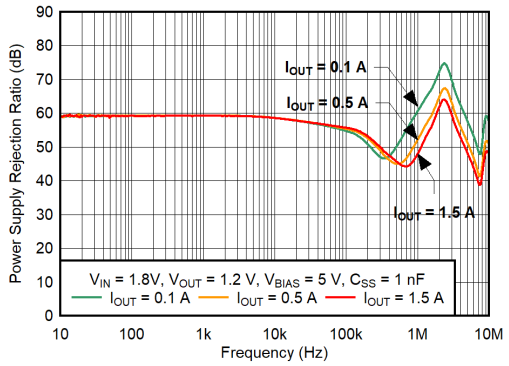


Figure 7-10. V_{BIAS} PSRR vs Frequency

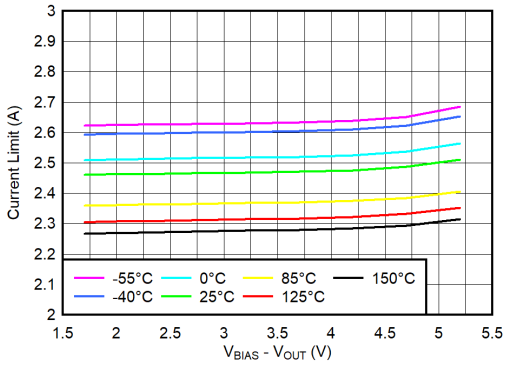


Figure 7-11. Current Limit vs (V_{BIAS} – V_{OUT})

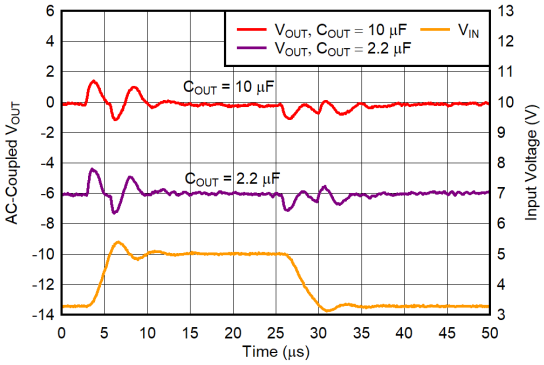


Figure 7-12. V_{BIAS} Line Transient

7.3 Power Supply Recommendations

The TPS748 is designed to operate from an input voltage up to 5.5 V, provided the bias rail is at least 1.62 V higher than the input supply and dropout requirements are met. The bias rail and the input supply must both provide adequate headroom and current for the device to operate normally. Connect a low output impedance power supply directly to the IN pin of the TPS748. This supply must have at least 1 µF of capacitance near the IN pin for optimal performance. A supply with similar requirements must also be connected directly to the bias rail with a separate 1-µF or larger capacitor. If the IN pin is tied to the bias pin, a minimum 4.7 µF of capacitance is needed for performance. To increase the overall PSRR of the solution at higher frequencies, use a pi-filter or ferrite bead before the input capacitor.

7.4 Layout

7.4.1 Layout Guidelines

An optimal layout can greatly improve transient performance, PSR, and noise. To minimize the voltage drop on the input of the device during load transients, the capacitance on IN and BIAS must be connected as close as possible to the device. This capacitance also minimizes the effects of parasitic inductance and resistance of the input source and can, therefore, improve stability. To achieve optimal transient performance and accuracy, the top side of R_1 in Figure 7-1 must be connected as close as possible to the load. If BIAS is connected to IN, connect BIAS as close to the sense point of the input supply as possible. This connection minimizes the voltage drop on BIAS during transient conditions and can improve the turn-on response.

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Knowing the device power dissipation and proper sizing of the thermal plane that is connected to the thermal pad is critical to avoiding thermal shutdown and ensuring reliable operation. Power dissipation of the device depends on input voltage and load conditions and can be calculated using Equation 6:

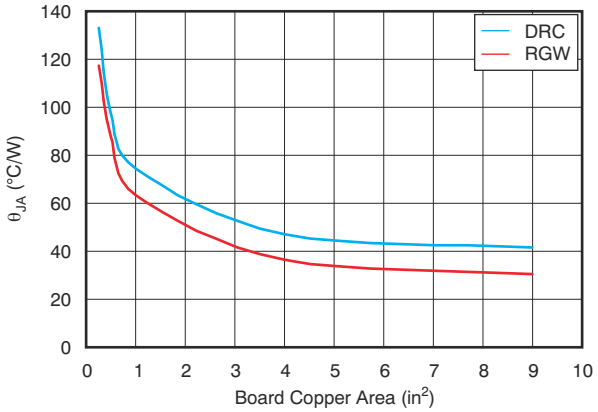
$$P_D = (V_{IN} - V_{OUT}) \times I_{OUT} \quad (6)$$

Power dissipation can be minimized and greater efficiency can be achieved by using the lowest possible input voltage necessary to achieve the required output voltage regulation.

On both the VSON (DRC) and VQFN (RGW) packages, the primary conduction path for heat is through the exposed pad to the printed circuit board (PCB). The pad can be connected to ground or be left floating; however, the pad be attached to an appropriate amount of copper PCB area to ensure the device does not overheat. The maximum junction-to-ambient thermal resistance depends on the maximum ambient temperature, maximum device junction temperature, and power dissipation of the device and can be calculated using Equation 7:

$$R_{\theta JA} = \frac{(+125°C - T_A)}{P_D} \quad (7)$$

Knowing the maximum $R_{\theta JA}$, the minimum amount of PCB copper area needed for appropriate heat sinking can be estimated using Figure 7-13.



$R_{\theta JA}$ value at board size of 9 in^2 (that is, 3 in × 3i n) is a JEDEC standard.

Figure 7-13. $R_{\theta JA}$ vs Board Size

Figure 7-13 shows the variation of $R_{\theta JA}$ as a function of ground plane copper area in the board. This figure is intended only as a guideline to demonstrate the effects of heat spreading in the ground plane and is not intended to be used to estimate actual thermal performance in real application environments.

Note

When the device is mounted on an application PCB, TI strongly recommends using Ψ_{JT} and Ψ_{JB}, as explained in the *Estimating Junction Temperature* section.

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7.4.1.1 Estimating Junction Temperature

Using the thermal metrics Ψ_{JT} and Ψ_{JB}, as shown in the *Thermal Information* table, the junction temperature can be estimated with corresponding formulas (given in Equation 8). For backwards compatibility, an older $\theta_{JC,Top}$ parameter is listed as well.

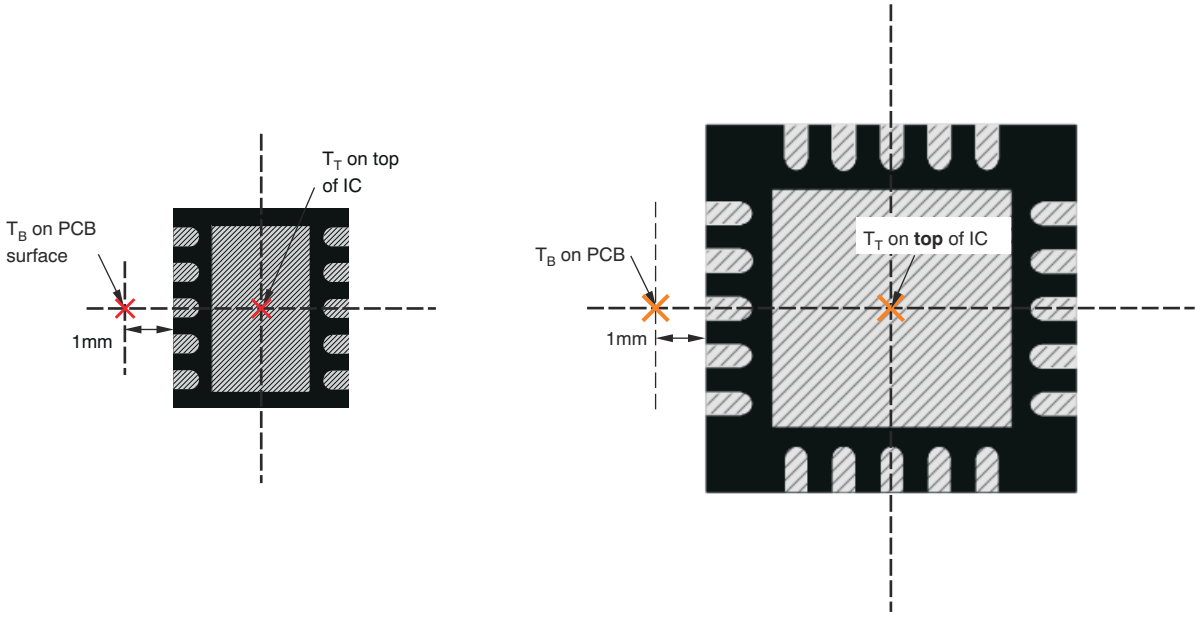
$$\Psi_{JT}: \quad T_J = T_T + \Psi_{JT} \bullet P_D$$
$$\Psi_{JB}: \quad T_J = T_B + \Psi_{JB} \bullet P_D \tag{8}$$

Where P_D is the power dissipation shown by Equation 6, T_T is the temperature at the center-top of the device package, and T_B is the PCB temperature measured 1 mm away from the device package *on the PCB surface* (Figure 7-14).

Note

Both T_T and T_B can be measured on actual application boards using a thermo-gun (an infrared thermometer).

For more information about measuring T_T and T_B, see the *Using New Thermal Metrics* application note, available for download at www.ti.com.



(a) Example DRC (SON) Package Measurement

(b) Example RGW (QFN) Package Measurement

Figure 7-14. Measuring Points for T_T and T_B

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By looking at Figure 7-15, the new thermal metrics (Ψ_{JT} and Ψ_{JB}) have very little dependency on board size. That is, using Ψ_{JT} or Ψ_{JB} with Equation 8 is a good way to estimate T_J by simply measuring T_T or T_B, regardless of the application board size.

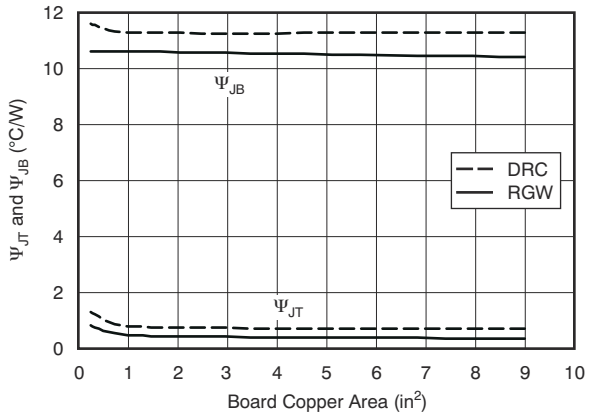


Figure 7-15. Ψ_{JT} and Ψ_{JB} vs Board Size

For a more detailed discussion of why TI does not recommend using $\theta_{JC(top)}$ to determine thermal characteristics, see the *Using New Thermal Metrics* application note, available for download at www.ti.com. For further information, see the *IC Package Thermal Metrics* application note, also available on the TI website.

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7.4.2 Layout Example

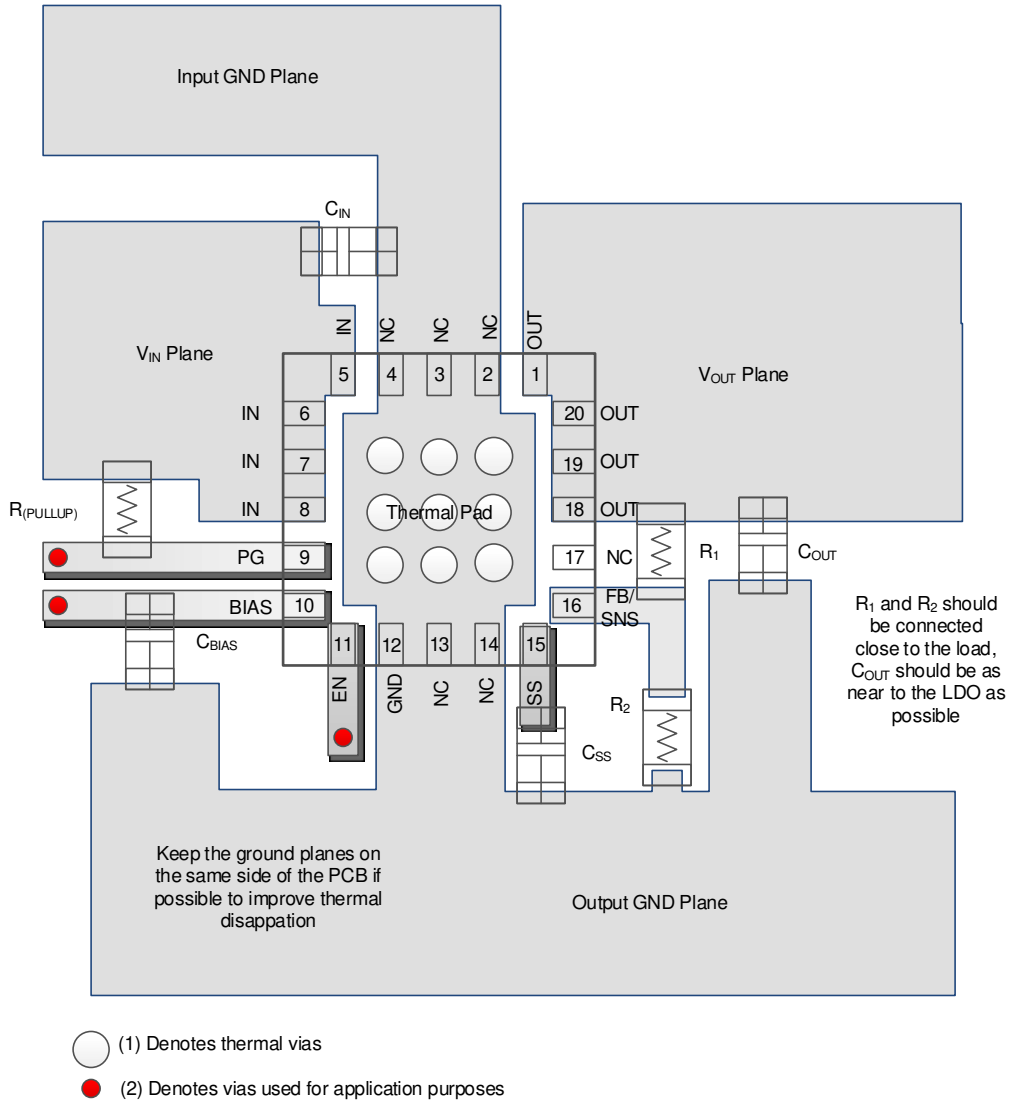


Figure 7-16. Layout Example (RGW Package)

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8 Device and Documentation Support

8.1 Device Support

8.1.1 Device Nomenclature

Table 8-1. Device Nomenclature

PRODUCT[1]	V_{OUT}
TPS74801**yyyzM3**	**yyy** is the package designator. **z** is the package quantity. **M3** is a suffix designator for devices that only use the latest manufacturing flow (CSO: RFB). Devices without this suffix ship with the legacy chip (CSO: DLN) or the new chip (CSO: RFB). The reel packaging label provides CSO information to distinguish which chip is being used. The device performance for new and legacy chips is denoted throughout the document.

(1) For the most current package and ordering information see the Package Option Addendum at the end of this document, or visit the device product folder on www.ti.com.

8.1.2 Development Support

8.1.2.1 Evaluation Modules

An evaluation module (EVM) is available to assist in the initial circuit performance evaluation using the TPS48. The TPS74801EVM-177 evaluation module (and related user's guide) can be requested at the Texas Instruments website through the product folders or purchased directly from the TI eStore.

8.1.2.2 Spice Models

Computer simulation of circuit performance using SPICE is often useful when analyzing the performance of analog circuits and systems. A SPICE model for the TPS748 is available through the product folders under *Tools & Software*.

8.2 Documentation Support

8.2.1 Related Documentation

For related documentation, see the following:

- Texas Instruments, *Using New Thermal Metrics* application note
- Texas Instruments, *Semiconductor and IC Package Thermal Metrics* application note
- Texas Instruments, *Ultimate Regulation with Fixed Output Versions of TPS742xx, TPS743xx, and TPS744xx* application note
- Texas Instruments, *Pros and Cons of Using a Feed-Forward Capacitor with a Low Dropout Regulator* application note
- Texas Instruments, *TPS74701EVM-177 and TPS74801EVM-177* user's guide

8.3 Receiving Notification of Documentation Updates

To receive notification of documentation updates, navigate to the device product folder on ti.com. Click on *Notifications* to register and receive a weekly digest of any product information that has changed. For change details, review the revision history included in any revised document.

8.4 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

Linked content is provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of Use.

8.5 Trademarks

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8.6 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

8.7 Glossary

TI Glossary — This glossary lists and explains terms, acronyms, and definitions.

9 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

Changes from Revision M (April 2023) to Revision N (June 2024)	Page
• Changed M3 references to *new chip*	1
• Changed *2% accuracy* to *1% accuracy (new chip)* in *Description* section	1
• Added new chip plots to *Typical Characteristics* sections	8
• Added *New Chip Functional Block Diagram* to *Functional Block Diagrams* section	16
• Changed *Standard Capacitor Values for Programming the Soft-Start Time* table: corrected equation in footnote and added *soft-start time* column for new chip	20
• Changed both *Application Curves* sections in *Typical Applications* to use new chip curves	26
• Added *Device Nomenclature* section	33

Changes from Revision L (March 2017) to Revision M (April 2023)	Page
• *Updated the numbering format for tables, figures, and cross-references throughout the document*	1
• Changed QFN to VQFN throughout document	1
• Added M3 devices to document and added M3-specific *Electrical Characteristics* table and *Typical Characteristics* sections	1
• Added links to *Applications* section	1

10 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package | Pins	Package qty | Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TPS74801DRCR	Active	Production	VSON (DRC) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCR.A	Active	Production	VSON (DRC) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCRG4	Active	Production	VSON (DRC) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCRM3	Active	Production	VSON (DRC) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCRM3.A	Active	Production	VSON (DRC) | 10	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCT	Active	Production	VSON (DRC) | 10	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCT.A	Active	Production	VSON (DRC) | 10	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801DRCTG4	Active	Production	VSON (DRC) | 10	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	BTO
TPS74801RGWR	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWR.A	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWRG4	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWRM3	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWRM3.A	Active	Production	VQFN (RGW) | 20	3000 | LARGE T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWT	Active	Production	VQFN (RGW) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWT.A	Active	Production	VQFN (RGW) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801
TPS74801RGWTG4	Active	Production	VQFN (RGW) | 20	250 | SMALL T&R	Yes	NIPDAU	Level-2-260C-1 YEAR	-40 to 125	TPS 74801

(1) **Status:** For more details on status, see our product life cycle.

(2) **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

(3) **RoHS values:** Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

(4) **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

(5) **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

(6) **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

OTHER QUALIFIED VERSIONS OF TPS74801 :

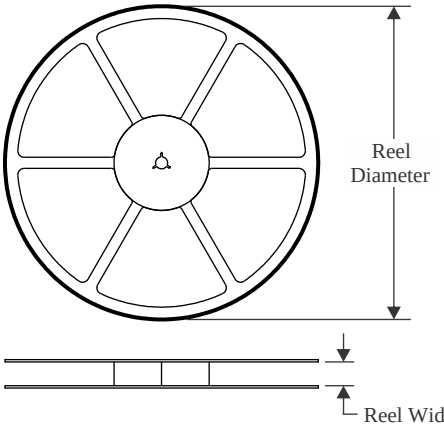
- Automotive : TPS74801-Q1

NOTE: Qualified Version Definitions:

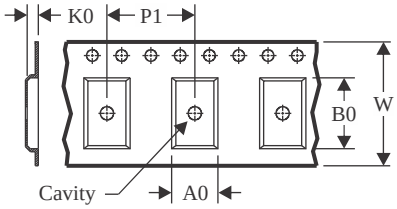
- Automotive - Q100 devices qualified for high-reliability automotive applications targeting zero defects

TAPE AND REEL INFORMATION

REEL DIMENSIONS

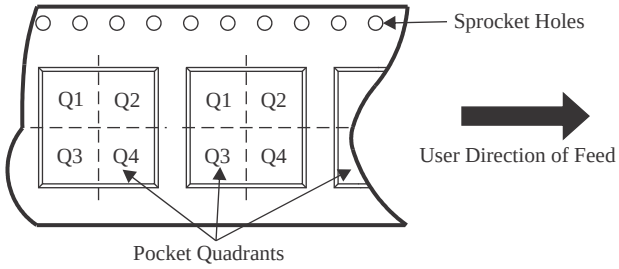


TAPE DIMENSIONS



A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

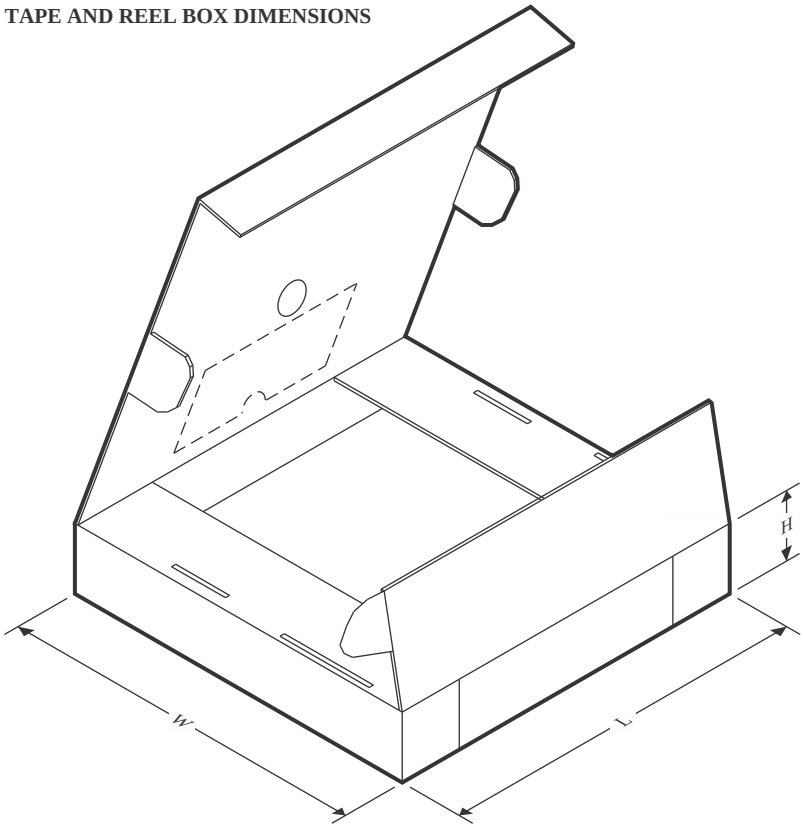
QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS74801DRCR	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS74801DRCRM3	VSON	DRC	10	3000	330.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS74801DRCT	VSON	DRC	10	250	180.0	12.4	3.3	3.3	1.1	8.0	12.0	Q2
TPS74801RGWR	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TPS74801RGWR	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TPS74801RGWRM3	VQFN	RGW	20	3000	330.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2
TPS74801RGWT	VQFN	RGW	20	250	180.0	12.4	5.3	5.3	1.1	8.0	12.0	Q2

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS74801DRCR	VSON	DRC	10	3000	360.0	360.0	36.0
TPS74801DRCRM3	VSON	DRC	10	3000	367.0	367.0	35.0
TPS74801DRCT	VSON	DRC	10	250	210.0	185.0	35.0
TPS74801RGWR	VQFN	RGW	20	3000	360.0	360.0	36.0
TPS74801RGWR	VQFN	RGW	20	3000	367.0	367.0	35.0
TPS74801RGWRM3	VQFN	RGW	20	3000	367.0	367.0	35.0
TPS74801RGWT	VQFN	RGW	20	250	210.0	185.0	35.0

GENERIC PACKAGE VIEW

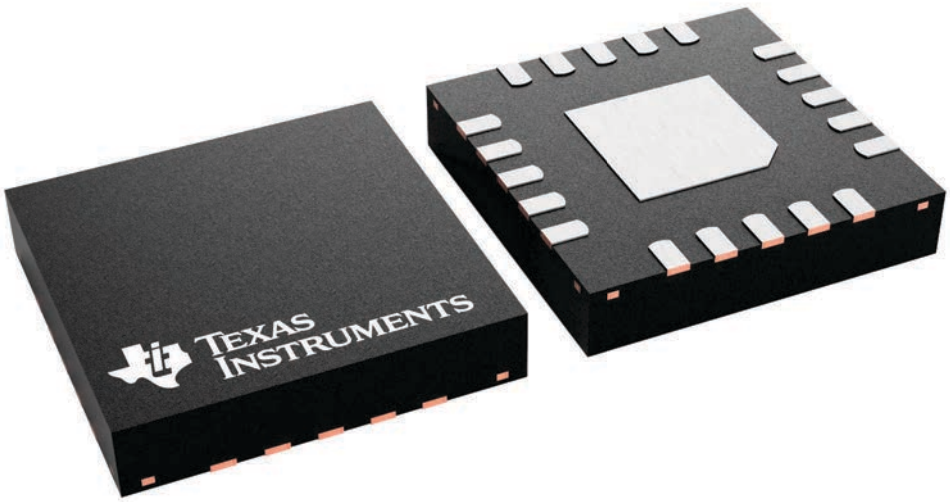
RGW 20

VQFN - 1 mm max height

5 x 5, 0.65 mm pitch

PLASTIC QUAD FLATPACK - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



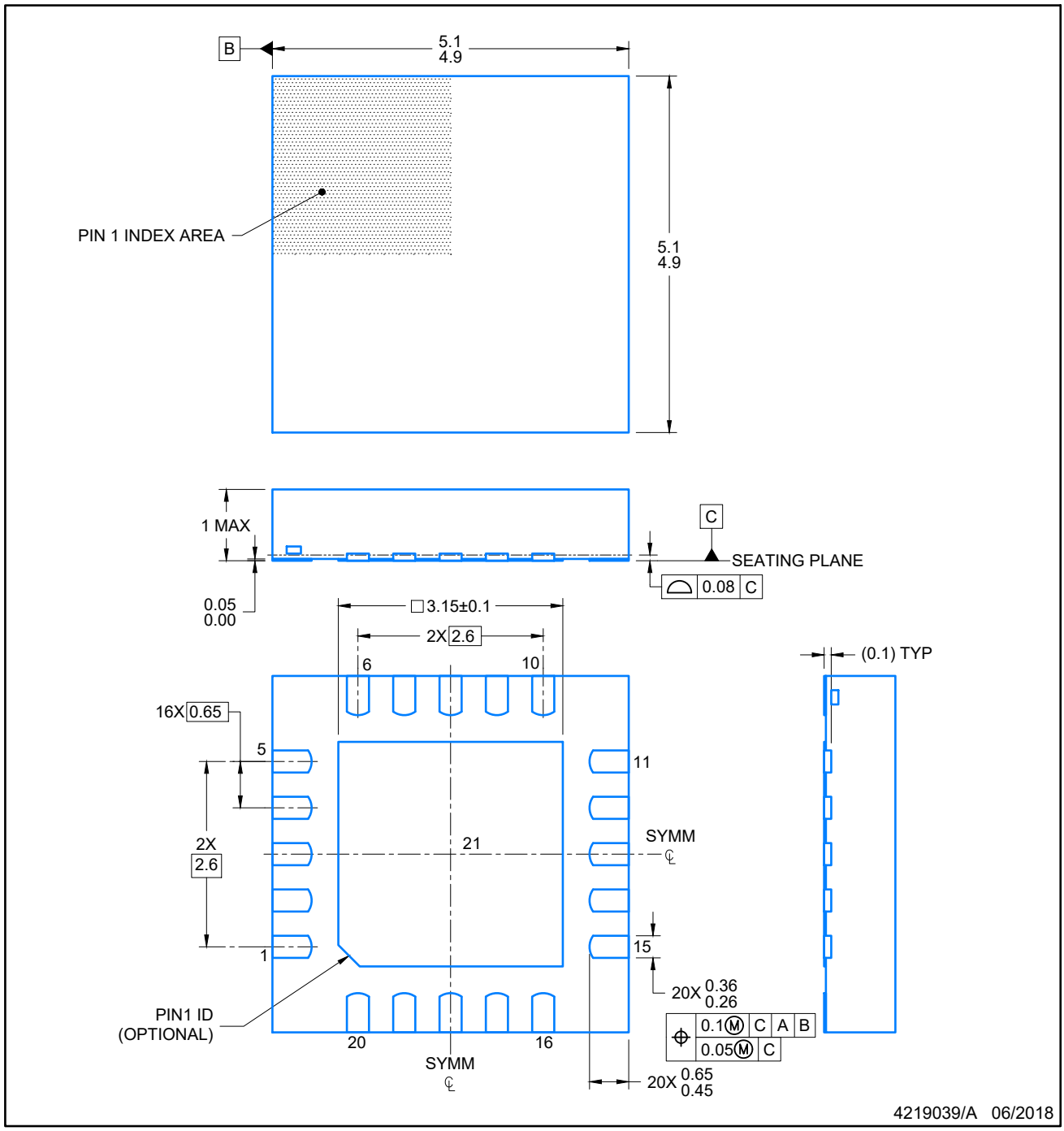
4227157/A

PACKAGE OUTLINE

RGW0020A

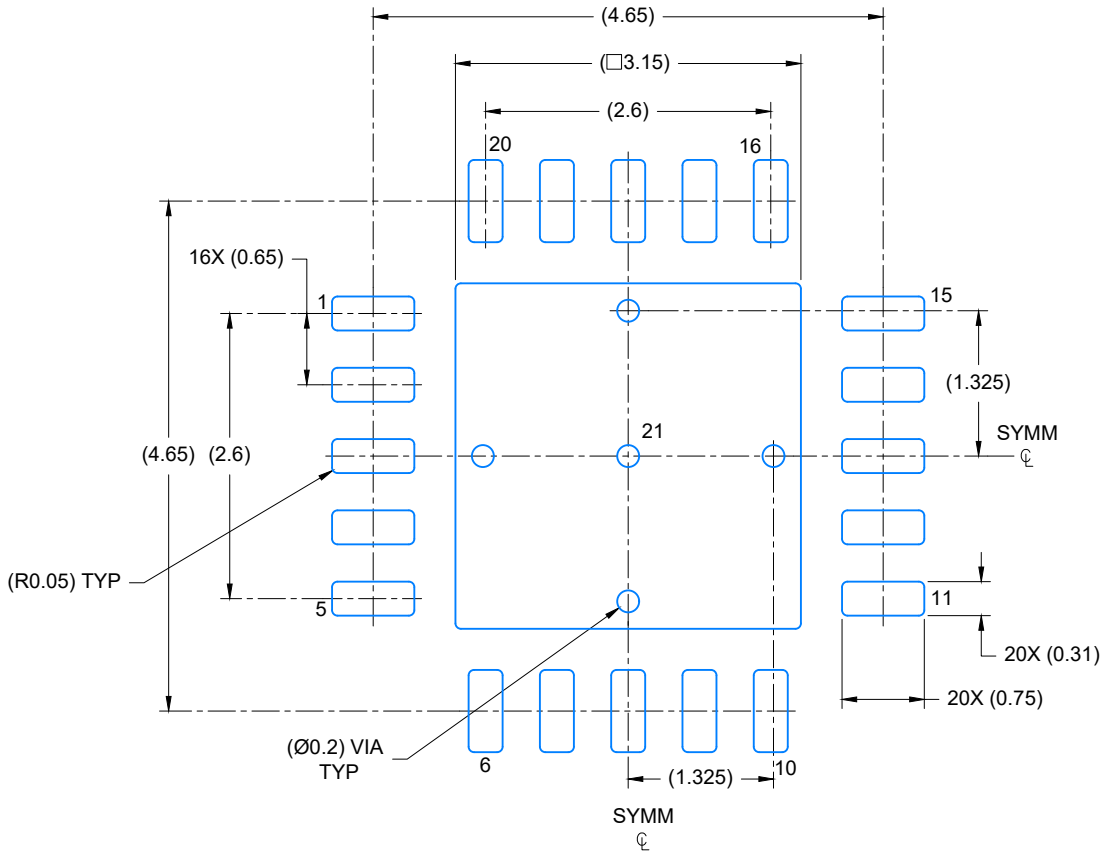
VQFN - 1 mm max height

PLASTIC QUAD FLATPACK-NO LEAD



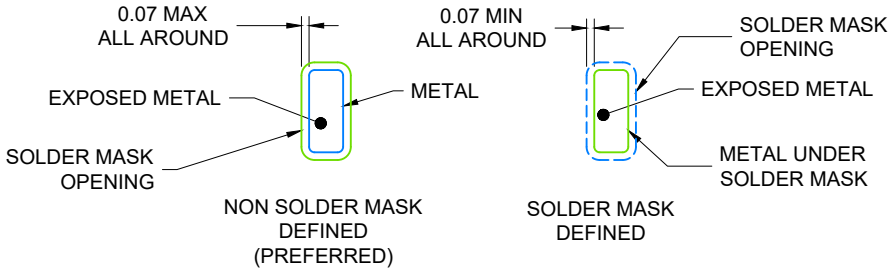
NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE

SCALE: 15X

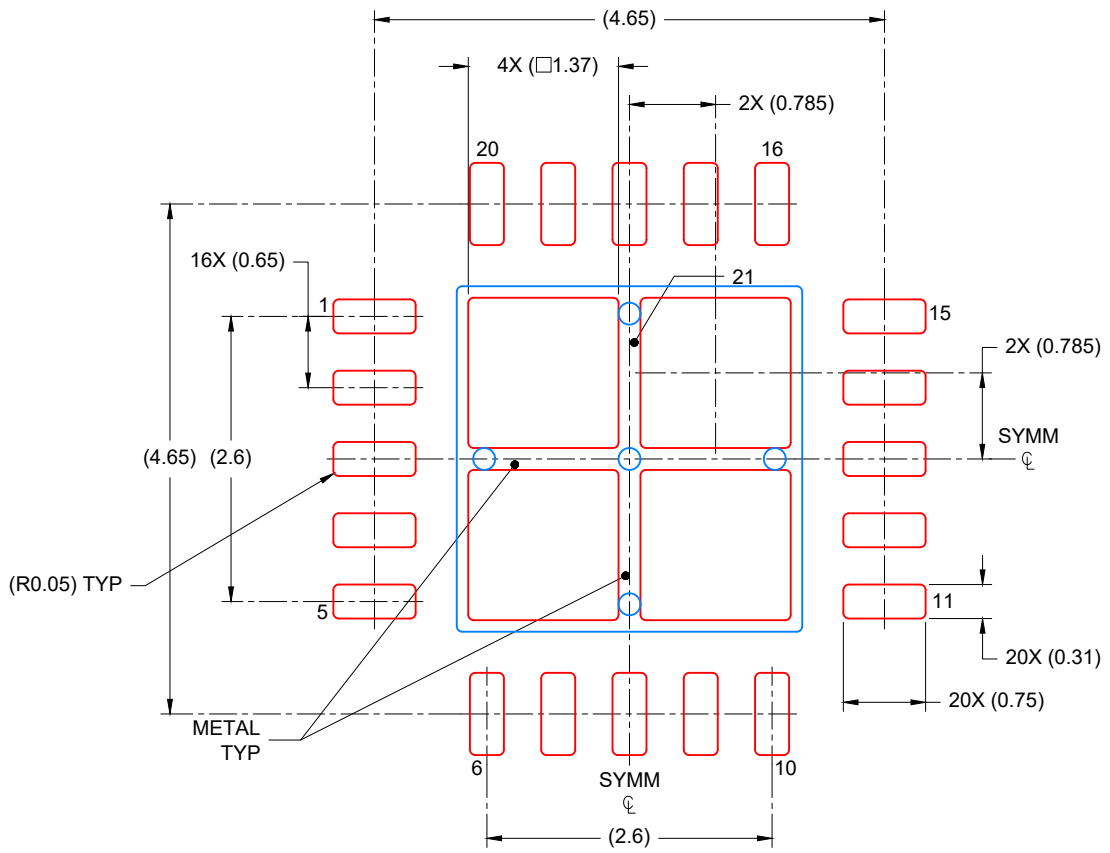


SOLDER MASK DETAILS

4219039/A 06/2018

NOTES: (continued)

4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD
75% PRINTED COVERAGE BY AREA
SCALE: 15X

4219039/A 06/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

GENERIC PACKAGE VIEW

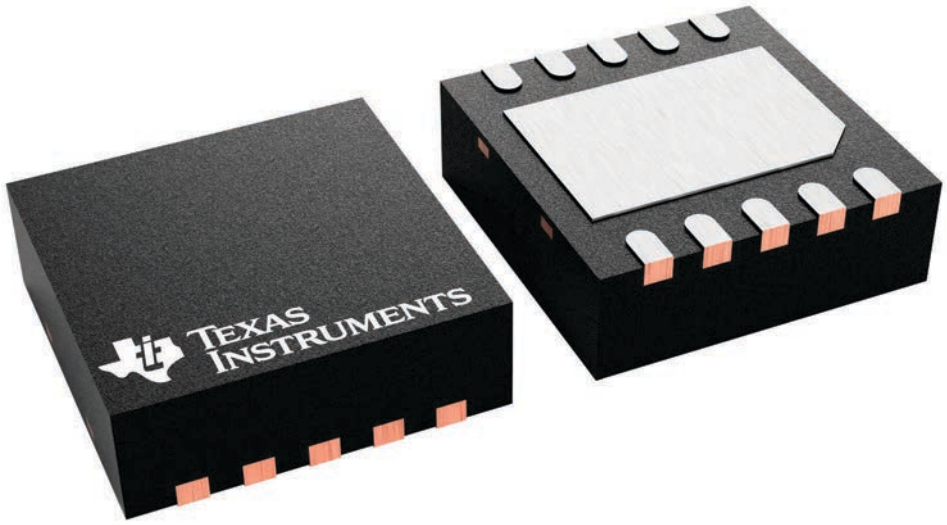
DRC 10

VSON - 1 mm max height

3 x 3, 0.5 mm pitch

PLASTIC SMALL OUTLINE - NO LEAD

This image is a representation of the package family, actual package may vary.
Refer to the product data sheet for package details.



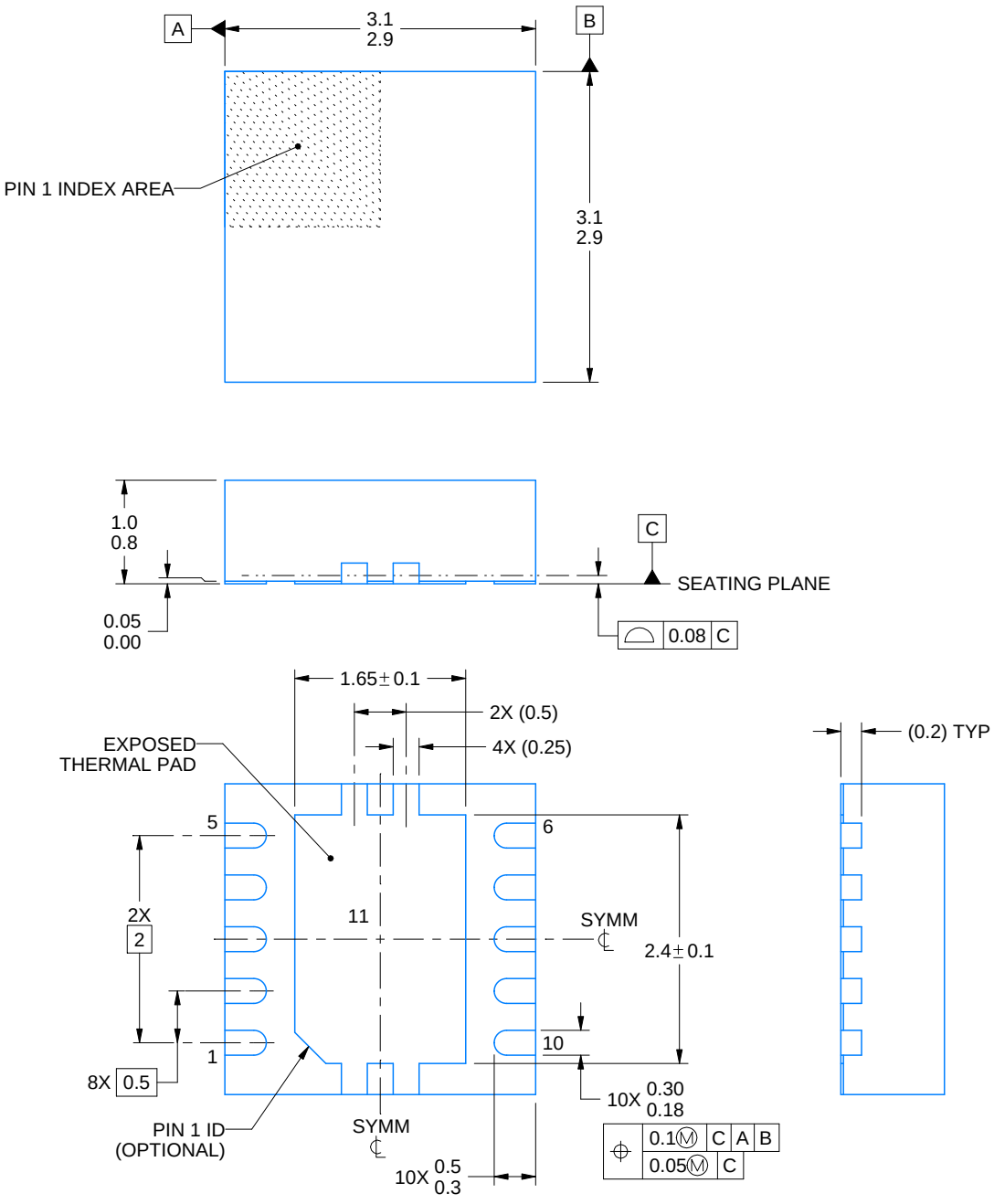
4226193/A

DRC0010J

PACKAGE OUTLINE

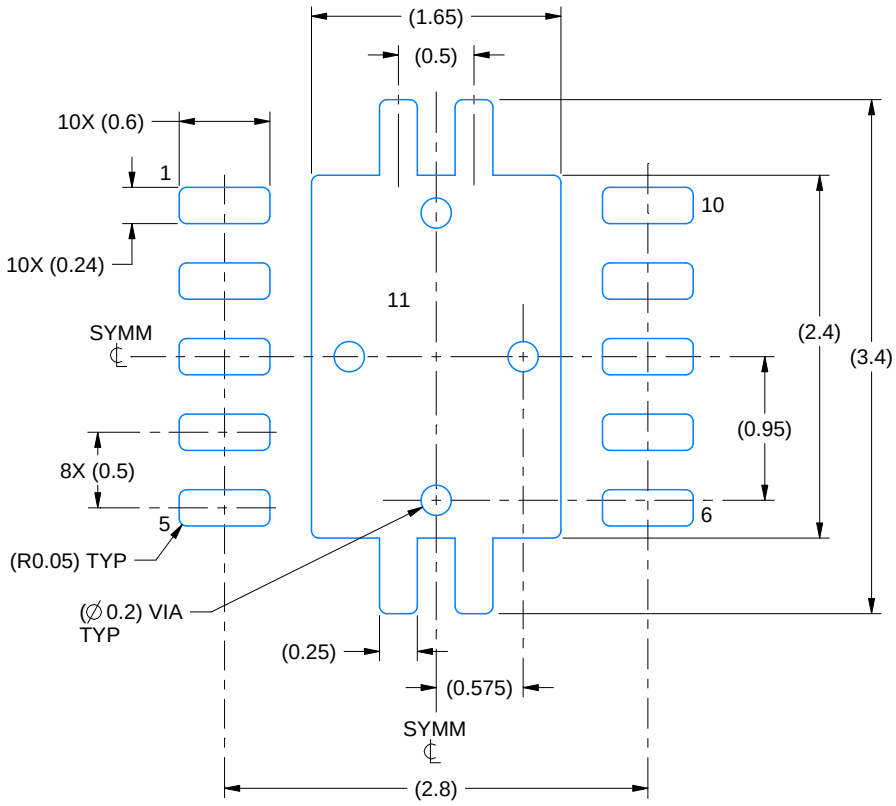
VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD

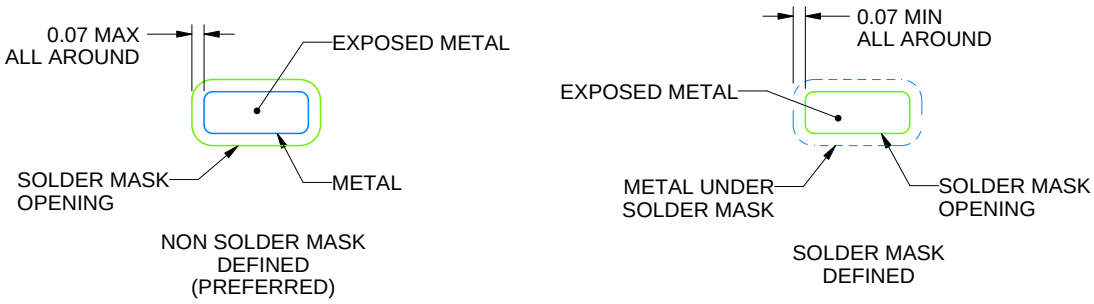


NOTES:

1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. The package thermal pad must be soldered to the printed circuit board for optimal thermal and mechanical performance.



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:20X



SOLDER MASK DETAILS

4218878/B 07/2018

NOTES: (continued)

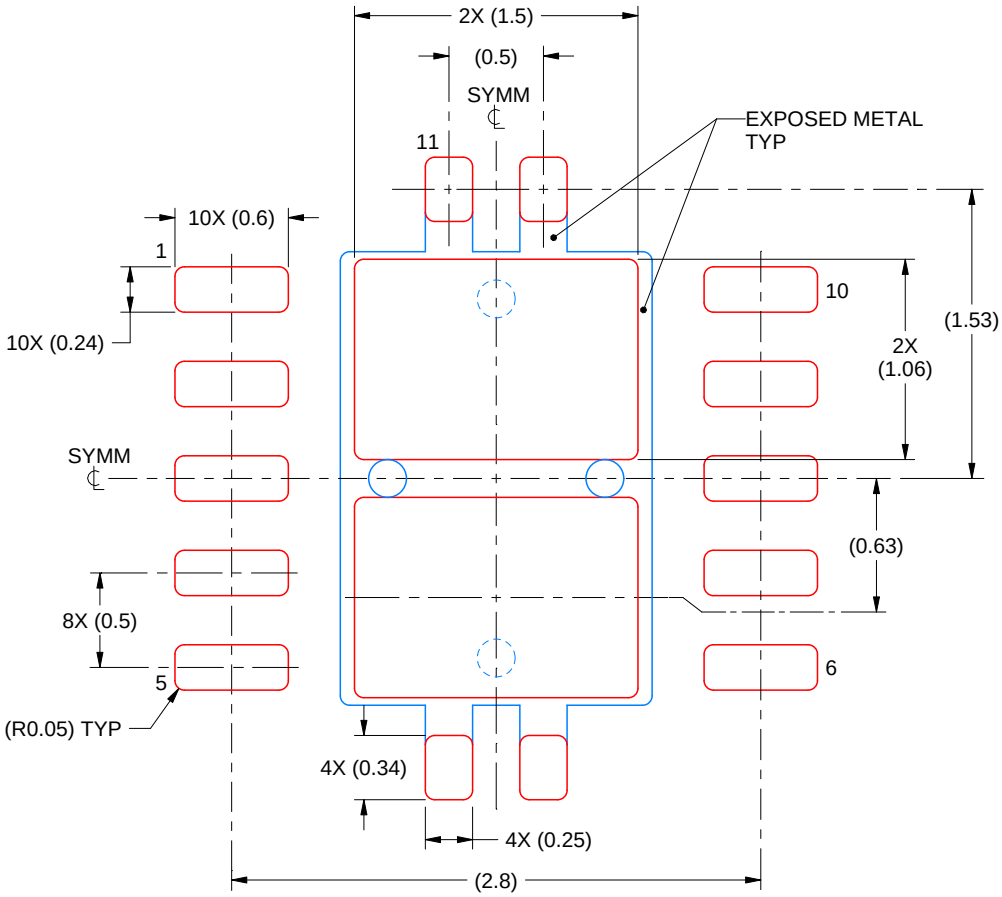
4. This package is designed to be soldered to a thermal pad on the board. For more information, see Texas Instruments literature number SLUA271 (www.ti.com/lit/slua271).
5. Vias are optional depending on application, refer to device data sheet. If any vias are implemented, refer to their locations shown on this view. It is recommended that vias under paste be filled, plugged or tented.

EXAMPLE STENCIL DESIGN

DRC0010J

VSON - 1 mm max height

PLASTIC SMALL OUTLINE - NO LEAD



SOLDER PASTE EXAMPLE
BASED ON 0.125 mm THICK STENCIL

EXPOSED PAD 11:
80% PRINTED SOLDER COVERAGE BY AREA
SCALE:25X

4218878/B 07/2018

NOTES: (continued)

6. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.

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